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# New Type of 2D Perovskites with Alternating Cations in the Interlayer Space, $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_n\text{Pb}_n\text{I}_{3n+1}$ : Structure, Properties and Photovoltaic Performance

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**ABSTRACT**

We present the new homologous series,  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_n\text{Pb}_n\text{I}_{3n+1}$  ( $n = 1, 2, 3$ ), of layered 2D perovskites. Structural characterization by single-crystal X-ray diffraction reveals that these compounds adopt an unprecedented structure type which is stabilized by the alternating ordering of the guanidinium and methylammonium cations in the interlayer space (ACI). Compared to the more common Ruddlesden-Popper (RP) 2D perovskites, the ACI perovskites have a different stacking motif and adopt a higher crystal symmetry. The higher symmetry of the ACI perovskites is expressed in its physical properties, which show a characteristic decrease of the bandgap with respect to their RP perovskite counterparts with the same perovskite layer thickness ( $n$ ). The compounds show a monotonic decrease in the optical gap as  $n$  increases:  $E_g = 2.27$  eV for  $n = 1$  to  $E_g = 1.99$  eV for  $n = 2$  and  $E_g = 1.73$  eV for  $n = 3$ , which show slightly narrower gaps compared to the corresponding RP perovskites. First-principles theoretical electronic structure calculations confirm the experimental optical gap trends suggesting that the ACI perovskites are direct bandgap semiconductors with wide valence and conduction bandwidths. To assess the potential of the ACI perovskites towards solar cell applications, we studied the  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_3\text{Pb}_3\text{I}_{10}$  ( $n = 3$ ) compound. Compact thin films from the  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_3\text{Pb}_3\text{I}_{10}$  compound with excellent surface coverage can be obtained from the anti-solvent dripping method. Planar photovoltaic devices from optimized ACI perovskite films yield a power-conversion-efficiency of 7.26% with a high open-circuit voltage of  $\sim 1$  V and a striking fill factor of  $\sim 80\%$ .

## INTRODUCTION

Two-dimensional (2D) layered halide perovskites are highly promising candidates for optoelectronic applications, and this has sparked new investigations of these materials from the synthetic, physicochemical and applications point of view.<sup>1-8</sup> Unlike the more extensively studied three-dimensional (3D)  $AMX_3$  perovskites ( $A^+ = Cs, CH_3NH_3$  (MA) or  $HC(NH_2)_2$  (FA)) where the possibility of a 3D stable crystal structure is limited by the size and shape of the  $A^+$  cation<sup>9-10</sup> the lower-dimensional perovskite semiconductors offer a much higher degree of structural versatility and permit better control and fine-tuning of the optoelectronic properties.<sup>11</sup> Conceptually, upon “cutting” the 3D parent compound along a specific crystallographic plane, infinite nanosheets with a slab thickness of atomic or molecular size can be obtained, which are separated by organic cations acting as spacers and in this context, they can be considered as natural quantum wells (QWs). These ultrathin negatively charged perovskite nanosheets are held together by intercalating organic cations, which balance the charge and support the structural integrity of the 2D perovskites. Depending on the cut in the 3D framework, the 2D perovskites can be subcategorized as  $\langle 100 \rangle$ ,  $\langle 110 \rangle$ , and  $\langle 111 \rangle$ -oriented perovskites. What effectively determines this crystallographic cut is the size and shape of the spacer cation. Cations employed for this purpose to date include, but not limited to, ammonium,<sup>1, 6, 12-15</sup> amidinium,<sup>16-17</sup> imidazolium<sup>18</sup> and phosphonium<sup>19</sup> ions. Among the  $\langle 100 \rangle$  perovskites, the Ruddlesden-Popper (RP) perovskites,<sup>20-21</sup> are by far the most common structural type with less common types being the Dion-Jacobson (DJ),<sup>22-23</sup> and Aurivillius (AV)<sup>24-26</sup> phases both of which finding paradigms only in oxide perovskite families. The less common DJ phases are chemically different from the RP phases in that the two spacer cations (M)<sub>2</sub> of the (M)<sub>2</sub>A<sub>n-1</sub>B<sub>n</sub>O<sub>3n+1</sub> RP structure are replaced by

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3 a single alkali metal M' spacer in the  $M'A_{n-1}B_nO_{3n+1}$  DJ structure. The AV perovskites have a  
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5 closer relationship to the RP compounds, but they are distinctively different because the  
6  
7 individual M cations are replaced by extended cationic  $[(Bi_2O_2)^{2+}]_{\infty}$  layers, which drastically  
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9 change the physical properties of the compounds.<sup>27-28</sup> From the crystallographic viewpoint, the  
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11 DJ phases are accompanied by a relative shift of the layers along the *ab*-plane ( $\frac{1}{2}$ , 0 shift,  
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13  $KLaNb_2O_7$ -type)<sup>29</sup> or no shift at all (0, 0 shift,  $CsLaNb_2O_7$ -type)<sup>30</sup> in the perovskite layers,  
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17 contrary to the RP phases that universally exhibit a ( $\frac{1}{2}$ ,  $\frac{1}{2}$ ) shift. The ( $\frac{1}{2}$ , 0) case results in an  
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19 'eclipsed' configuration of the layers along the stacking direction. The structural chemistry of the  
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21 DJ oxide perovskites has recently undergone a resurgence after the predictions that such  
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23 structures can exhibit ferroelectricity<sup>31-32</sup> using certain material design principles.<sup>33</sup> Despite the  
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25 abundance of DJ perovskites in oxides,<sup>34</sup> this structural type is hitherto unknown in the hybrid  
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27 halide perovskites.  
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32 Herein we report on the  $(C(NH_2)_3)(CH_3NH_3)_nPb_nI_{3n+1}$  ( $n = 1-3$ ) family of 2D perovskites, new  
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34 type of 2D halide perovskite which feature two different alternating cations in the interlayer  
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36 space (ACI). This results in cation-ordering in the interlayer space with the two spacer cations  
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38 being guanidinium  $(C(NH_2)_3, GA)^+$  and methylammonium  $(CH_3NH_3, MA)^+$ . This unique  
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40 ordering leads to the formation of an unprecedented structure type which blends the chemical  
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42 formula of the RP perovskites with the structural features of the DJ perovskites. The ordering of  
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44 the cations leads to a ( $\frac{1}{2}$ , 0) shift of the layers reminiscent of the DJ perovskites but at the same  
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46 differing in the occupation of the interlayer sites due to charge balance restrictions, thus leading  
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48 to a different centering of the unit cell (Table 1). GA was chosen as a spacer since it has a  
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50 structural formula reminiscent of the formamidinium  $(HC(NH_2)_2, FA)^+$  and iodoformamidinium  
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52  $(IC(NH_2)_2, IFO)^+$  cations, which stabilize the perovskite structure, either in its 3D form<sup>35</sup> or in  
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3 the <110> 2D perovskite,<sup>36</sup> respectively. Conceptually, GA is obtained by substituting the C-H  
4 hydrogen atom in FA or C-I iodine atom in IFO with an -NH<sub>2</sub> group. The present study expands  
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6 on the series of simple 2D guanidinium compounds that adopt the <110>-oriented RP perovskite  
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8 type, originally obtained by Szafranski and coworkers<sup>37-39</sup> and recently revisited by the  
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10 Hillebrecht's group.<sup>40</sup> The ACI perovskites reported in this work find join the very recently  
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12 reported GAC<sub>S<sub>n</sub></sub>Pb<sub>n</sub>X<sub>3n+1</sub> compounds which adopt a similar crystal structure.<sup>41</sup> Here the ACI  
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14 phase GAMA<sub>n</sub>Pb<sub>n</sub>I<sub>3n+1</sub> series (n = 1, 2 and 3) has been structurally characterized by means of  
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16 single-crystal X-ray diffraction. The compounds exhibit lower bandgaps and slightly reduced  
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18 photoluminescence (PL) intensity compared to the known Ruddlesden-Popper (RP) perovskites  
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20 having butylammonium (BA) spacers. The observed trend in the bandgap within the ACI series  
21  
22 can be captured by DFT calculations. They predict that ACI have slightly narrower (n = 1, 3) or  
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24 comparable (n = 2) bandgap compared to the RP perovskites for their corresponding n-member.  
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26 We also investigated the photovoltaic performance of the highest member of the series  
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28 GAMA<sub>3</sub>Pb<sub>3</sub>I<sub>10</sub> (n = 3), which adopts the centrosymmetric *Imma* space group and has the smallest  
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30 optical gap in the series,  $E_g = 1.73$  eV, making it a good candidate for a light absorber material in  
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32 both single-junction and tandem solar cells. Smooth, compact high-quality thin films were  
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34 obtained by employing the solvent-engineering method with anti-solvent dripping at an  
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36 optimized delay time. While the morphology improves drastically for the films before and after  
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38 anti-solvent treatment, the crystallinity is found to remain unaffected. Planar solar cells  
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40 comprising the optimized n = 3 films exhibit a promising power-conversion-efficiency (PCE) of  
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42 7.26% (average  $6.69 \pm 0.47\%$ ), with a high Voc of 0.974 V and an impressive fill factor (FF) of  
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44 ~80%, which is the highest value reported for 2D perovskite solar cells.  
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## EXPERIMENTAL

**Materials.** Lead oxide (PbO, 99%), methylamine hydrochloride (CH<sub>3</sub>NH<sub>3</sub>Cl, 99%), guanidine hydrochloride ((C(NH<sub>2</sub>)<sub>3</sub>Cl, ≥ 98%), hydriodic acid (HI, 57 wt% in H<sub>2</sub>O), hypophosphorous acid (H<sub>3</sub>PO<sub>2</sub>, 50 wt% in H<sub>2</sub>O), N,N-dimethylformamide (DMF, anhydrous, 99.8%), dimethylsulfoxide (DMSO, anhydrous, ≥ 99.9%), and chlorobenzene (CB, anhydrous, 99.8%) were used as received from Sigma-Aldrich without further purification. Poly(3,4-ethylenedioxythiophene)-poly(styrenesulfonate) (PEDOT:PSS) and phenyl-C61-butyric acid methyl ester (PC<sub>61</sub>BM, > 99%) were purchased from Clevios and American Dye Source Inc., respectively.

**Materials Synthesis.** ((C(NH<sub>2</sub>)<sub>3</sub>)<sub>2</sub>PbI<sub>4</sub>. PbO (670 mg, 3 mmol) was dissolved in a mixture of 20.0 ml of aqueous HI and 1.7 ml of aqueous H<sub>3</sub>PO<sub>2</sub> by heating to boiling under constant magnetic stirring for at least 15 min. To the hot bright yellow solution was added solid C(NH<sub>2</sub>)<sub>3</sub>Cl (573 mg, 6 mmol), and the reaction was kept under constant heating and stirring for a few hours until ~25% of the acid solution has evaporated. The stirring was then discontinued, and the hot supersaturated solution was slowly quenched to room temperature. Bright yellow plate-like crystals precipitated after the solution was allowed to stand for 2 days. The crystals were isolated by suction filtration and thoroughly dried at 60 °C in a vacuum oven (Yield: 0.66g, 26% based on total Pb).

(C(NH<sub>2</sub>)<sub>3</sub>)(CH<sub>3</sub>NH<sub>3</sub>)PbI<sub>4</sub>. PbO (670 mg, 3 mmol) was dissolved in a mixture of 20.0 ml of aqueous HI and 1.7 ml of aqueous H<sub>3</sub>PO<sub>2</sub> by heating to boiling under constant magnetic stirring for at least 15 min. To the hot bright yellow solution were added solids CH<sub>3</sub>NH<sub>3</sub>Cl (203 mg, 3

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3 mmol) and  $C(NH_2)_3Cl$  (287 mg, 3 mmol), and the reaction was kept under constant heating and  
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5 stirring for a few hours until ~25% of the acid solution has evaporated. The stirring was then  
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7 discontinued, and as the hot supersaturated solution was slowly cooled to room temperature. Red  
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9 crystals precipitated after the solution was allowed to stand for 2 days. The crystals were isolated  
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11 by suction filtration and thoroughly dried at 60 °C in a vacuum oven (Yield: 0.54g, 22% based  
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13 on total Pb).  
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18  $(C(NH_2)_3)(CH_3NH_3)_2Pb_2I_7$ . PbO (2232 mg, 10 mmol) was dissolved in a mixture of 20.0 ml of  
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20 aqueous HI and 1.7 ml of aqueous  $H_3PO_2$  by heating to boiling under constant magnetic stirring  
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22 for at least 15 min. To the hot bright yellow solution were added solids  $CH_3NH_3Cl$  (675 mg, 10  
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24 mmol) and  $C(NH_2)_3Cl$  (478 mg, 5 mmol), and the reaction was kept under constant heating until  
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26 all the the reactants dissolved. The stirring was then discontinued, and as the hot supersaturated  
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28 solution was slowly quenched to room temperature, upon which the precipitation of dark red  
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30 crystals commenced. The crystals were allowed to settle for further 2 h, before the crystals were  
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32 isolated by suction filtration and thoroughly dried at 60 °C in a vacuum oven (Yield: 1.64g, 23%  
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34 based on total Pb).  
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40  $(C(NH_2)_3)(CH_3NH_3)_3Pb_3I_{10}$ . PbO (2232 mg, 10 mmol) was dissolved in a mixture of 20.0 ml of  
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42 aqueous HI and 1.7 ml of aqueous  $H_3PO_2$  by heating to boiling under constant magnetic stirring  
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44 for at least 15 min. To the hot bright yellow solution were added solids  $CH_3NH_3Cl$  (675 mg, 10  
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46 mmol) and  $C(NH_2)_3Cl$  (318 mg, 3.33 mmol), and the reaction was kept under constant heating  
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48 until all the the reactants dissolved. The stirring was then discontinued, and as the hot  
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50 supersaturated solution was slowly quenched to room temperature, upon which the precipitation  
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52 of black crystals commenced. The crystals were allowed to settle for further 2 h, before the  
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3 crystals were isolated by suction filtration and thoroughly dried at 60 °C in a vacuum oven  
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5 (Yield: 1.50g, 22% based on total Pb).  
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9 **Materials Characterization.** High resolution synchrotron powder X-ray diffraction (SXRD)  
10 data were collected at beamline 11-BM-B of the Advanced Photon Source (APS), Argonne  
11 National Laboratory using  $\lambda = 0.517040 \text{ \AA}$ . Discrete detectors covering an angular range from 0  
12 to  $4^\circ 2\theta$  are scanned over a  $26^\circ 2\theta$  range, with data points collected every  $0.001^\circ 2\theta$  and a scan  
13 speed of 0.1°/s.  
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20 Scanning Electron Microscopy (SEM) images of the perovskite crystals were obtained by using a  
21 Hitachi SU3400 equipped with an electron beam accelerated at 10-20 kV.  
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25 A Shimadzu UV-3600 PC double-beam, double-monochromator spectrophotometer was used to  
26 acquire room-temperature optical diffuse reflectance spectra of the powdered samples in the  
27 range of 200-2500 nm. BaSO<sub>4</sub> was used as a non-absorbing reflectance reference, and  
28 reflectance data were converted to absorbance data via Kubelka–Munk transformation.<sup>42-44</sup>  
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34 Photoluminescence spectra were collected on oriented crystals using Horiba LabRam Evolution  
35 high-resolution confocal Raman microscope spectrometer (600 g/mm diffraction grating)  
36 equipped with a diode CW laser (473 nm, 25 mW) and a Synapse CCD camera.  
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41 Single-crystal X-ray diffraction experiments were performed using a STOE IPDS II or IPDS 2T  
42 diffractometer with Mo K $\alpha$  radiation ( $\lambda = 0.71073 \text{ \AA}$ ) and operating at 50 kV and 40 mA.  
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44 Integration and numerical absorption corrections were performed using the X-AREA, X-RED,  
45 and X-SHAPE programs. The structures were solved by charge flipping and refined by full-  
46 matrix least squares on  $F^2$  using the Jana2006 package.<sup>45</sup> The PLATON software<sup>46</sup> was used to  
47 identify the twinning domains and validate the space groups of the compounds.  
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3 **Theoretical calculations.** First-principles calculations are based on density functional theory  
4 (DFT) as implemented in the Siesta package.<sup>47</sup> Calculations have been carried out with the GGA  
5 functional in the PBE form, using the experimentally determined crystal structures.<sup>48</sup> Spin-orbit  
6 coupling is taken into account through the on-site approximation as proposed by Fernández-  
7 Seivane *et al.*<sup>49</sup> Core electrons are described with Troullier-Martins pseudopotentials.<sup>50</sup> The  
8 valence wavefunction is developed over a double- $\zeta$  polarized basis set of finite-range numerical  
9 pseudoatomic orbitals.<sup>51</sup> An energy cutoff of 150 Ry for real-space mesh size is used as well as a  
10  $1 \times 4 \times 4$   $k$ -point sampling grid for sampling the Brillouin zone.

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12 **Thin Film Characterization.** AFM images were acquired using a Dimensional Icon Scanning  
13 Probe Microscope (Veeco) in tapping mode. Powder X-ray diffraction measurements were  
14 carried out on a Rigaku MiniFlex600 X-ray diffractometer (Cu  $K\alpha$  radiation,  $\lambda = 1.5406 \text{ \AA}$ )  
15 operating at 40 kV and 15 mA. GIWAXS measurements were performed at Beamline 8-ID-E of  
16 the Advanced Photon Source (APS) at Argonne National Laboratory. Samples prepared on  
17 Si/PEDOT:PSS substrates were exposed to an X-ray beam ( $\lambda = 1.6868 \text{ \AA}$ ) at an incident angle of  
18  $0.20^\circ$  for 5 s, and the scattered light was collected by a Pilatus 1 M pixel array detector at 204  
19 mm from the sample. Absorbance data were collected on Cary 6000i UV-Vis-NIR  
20 spectrophotometer in the 175-1800 nm region.

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22 **Solar Cell Device Fabrication.** The FTO-coated glass substrates (TEC7, 2.2 mm, Hartford  
23 Glass Co. Inc.) were cleaned by sequential sonication in aqueous detergent, deionized water,  
24 isopropanol (IPA), and acetone (ACE) for 15 min each, followed by a 5 min oxygen plasma  
25 treatment. A thin layer of PEDOT:PSS was deposited on the pre-cleaned FTO substrates by spin-  
26 coating at 6,000 rpm for 30 s and annealed at  $150^\circ \text{C}$  for 30 min in air. The substrates were then  
27 transferred to a nitrogen-filled glove box to complete the rest of the device fabrication. Solutions  
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3 of GAMA<sub>3</sub>Pb<sub>3</sub>I<sub>10</sub> were prepared by dissolving 300 mg of the oven-dried crystals in 1 ml of DMF  
4 and 100 μl of DMSO solvents. For perovskite thickness study, various concentrations of the  
5 compound (20 mg, 25 mg, 30 mg, 35 mg, and 40 mg) in 100 μl:10 μl DMF:DMSO were used.  
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10 The perovskite layer was deposited by spin-casting 60 μl of the as-prepared solution on the  
11 ITO/PEDOT:PSS substrates at 500 rpm. for 3s, followed by 4,000 rpm. for 60 s. For solvent-  
12 engineered films, 300 μl of CB anti-solvent was dropped on the spinning substrate at various  
13 delay times (3 s, 5 s, 10 s, 20 s, 30 s, 40 s, and 50 s), and the films turned brown instantaneously.  
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20 The substrates were then annealed at 80 °C for 15 min to ensure removal of any remaining  
21 solvent residuals. PC<sub>61</sub>BM layer was deposited on the perovskite film from a 20 mg/ml PC<sub>61</sub>BM  
22 solution in CB at 5,000 rpm. for 30 s. Finally, 150 nm of Al was thermally evaporated through a  
23 shadow mask at a pressure of  $\sim 2 \times 10^{-7}$  Torr. The active area of the device was 0.09 cm<sup>2</sup>.  
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30 **Solar Cell Device Characterization.** The current density vs. voltage (J-V) characteristics were  
31 collected in air without any encapsulation using a Keithley 2400 source meter under simulated  
32 AM 1.5G irradiation (100 mW/cm<sup>2</sup>) generated by a standard solar simulator (Abet  
33 Technologies). The light intensity was calibrated by using an NREL-certified monocrystalline Si  
34 reference cell to reduce the spectral mismatch.  
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## RESULTS AND DISCUSSION

**Materials synthesis.** The synthesis of the series of  $(\text{C}(\text{NH}_2)_3)_2\text{PbI}_4$  and  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_n\text{Pb}_n\text{I}_{3n+1}$  compounds was accomplished by mixing stoichiometric ratios of pre-dried guanidinium chloride (GACl,  $\text{C}(\text{NH}_2)_3\text{Cl}$ ), methylammonium chloride (MACl,  $\text{CH}_3\text{NH}_3\text{Cl}$ ), and lead oxide (PbO) in a hot HI solution. As soon as the supersaturated, clear, bright yellow solution was removed from the hot plate and left to cool to ambient temperature, crystals of the title compounds started forming. Bright yellow plates of  $(\text{C}(\text{NH}_2)_3)_2\text{PbI}_4$ , red needles of  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)\text{PbI}_4$ , dark red needles of  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_2\text{Pb}_2\text{I}_7$ , and black needles of  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_3\text{Pb}_3\text{I}_{10}$  were obtained, Figure 1. Unlike the RP perovskites, ACI perovskites obey a different synthetic protocol requiring a fully stoichiometric reaction in order to crystallize in pure form. This is presumably because of the higher solubility of guanidinium salts in the reaction medium, in contrast to the long aliphatic ammonium cations used in the synthesis of the RP perovskites. The synthetic procedure finds an additional obstacle in the form of the reaction by-product the yellow  $(\text{C}(\text{NH}_2)_3)\text{PbI}_3$ ,<sup>37</sup> a relatively insoluble one-dimensional (1D) “perovskitoid” of the  $\text{NH}_4\text{CdCl}_3$  structure-type which competes with the precipitation of the ACI perovskite phases.<sup>11</sup> The co-formation of two reaction products was also observed in the Sn-based GA systems<sup>11</sup> with the 2D perovskite  $(\text{C}(\text{NH}_2)_3)_2\text{SnI}_4$  being the kinetic reaction product

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3 and the 3D ((C(NH<sub>2</sub>)<sub>3</sub>)SnI<sub>3</sub>) perovskite being the thermodynamic product. However, in the case  
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5 of the (C(NH<sub>2</sub>)<sub>3</sub>)<sub>2</sub>PbI<sub>4</sub>/(C(NH<sub>2</sub>)<sub>3</sub>)PbI<sub>3</sub> system this tendency inverts with the (C(NH<sub>2</sub>)<sub>3</sub>)<sub>2</sub>PbI<sub>4</sub> being  
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7 the thermodynamic product and GAPbI<sub>3</sub> the kinetic one, possibly due to the lower  
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9 dimensionality of the 1D perovskitoid, which makes it easier to precipitate. With the hindsight of  
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11 the behavior of the pure guanidinium systems, we conducted the reactions to synthesize the  
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13 (C(NH<sub>2</sub>)<sub>3</sub>)(CH<sub>3</sub>NH<sub>3</sub>)<sub>n</sub>Pb<sub>n</sub>I<sub>3n+1</sub> (n = 1-3) perovskites under relatively low concentrations below the  
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15 saturation point of the solution, in order to avoid the formation of the 1D by-product.  
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20 All the ACI perovskites crystallize in high purity but their yield is relatively low (~25%)  
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22 due to the special synthetic considerations discussed above, Figure 1b. An exception is found for  
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24 (C(NH<sub>2</sub>)<sub>3</sub>)(CH<sub>3</sub>NH<sub>3</sub>)PbI<sub>4</sub> (the n = 1) member which shows a photo-instability (in solution and in  
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26 the solid state) towards decomposition to the higher n = 2 member, presumably through a  
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28 disproportionation mechanism. The photoreaction is not severe and it occurs only on the surface  
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30 of the crystallites. A similar photosensitivity has been observed for the similar cation iodo-  
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32 formamidinium cation n = 1 perovskite which degrades upon ambient light irradiation.<sup>52</sup> Another  
33  
34 important characteristic of the ACI perovskites that differentiates them from the RP perovskites  
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36 is their mechanical behavior. All ACI perovskites are brittle and tend to crack when mechanical  
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38 force is applied, as opposed to the RP perovskites that are more malleable and tend to undergo a  
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40 plastic deformation. As will be discussed below, the unique mechanical properties of the ACI  
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42 perovskites arise from their tight, more 3D-like crystal structure, which locks the layers in place  
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44 with respect to one another in contrast to the RP perovskites in which the floppy organic chains  
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46 of the spacers lend the materials additional flexibility.  
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53 **Description of the crystal structures.** The crystal structures of the homologous ACI perovskite  
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55 series, (GA)(MA)<sub>n</sub>Pb<sub>n</sub>I<sub>3n+1</sub> (n = 1-3), are illustrated in Figure 2; selected crystallographic data are  
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3 presented in Table 2, and selected bonding parameters are provided in Table 3. All compounds  
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5 crystallize in orthorhombic space groups with their unit cell dimensions being [ $a \times 2a \times$   
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7  $2(a \cdot n + x)$ ], where  $a \sim 6.3 \text{ \AA}$  is the lattice parameter of the idealized cubic 3D perovskite and  $x \sim$   
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9  $3.1 \text{ \AA}$  is the interlayer spacing (Table 2). The odd  $n$ -members ( $n = 1, n = 3$ ) adopt the  
10  
11 centrosymmetric *Imma* space group, whereas the even  $n$ -member ( $n = 2$ ) adopts the polar  
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13 noncentrosymmetric *Bmm2* space group. The difference in odd and even members of  
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15 homologous 2D perovskites series is expected as it arises from the changes in the  
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17 crystallographic symmetry element that bisects the perovskite layers themselves along the *ab*-  
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19 plane. For even  $n$ -members a mirror plane is present whereas for odd  $n$ -numbers this is replaced  
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21 by a glide plane.<sup>53</sup> As a consequence of this trend all even-numbered halide 2D perovskites that  
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23 bear MA as the “perovskitizer” cation tend to be noncentrosymmetric due to the incompatibility  
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25 of the  $\text{CH}_3\text{NH}_3^+$  cation of sitting on a mirror plane.<sup>6, 54</sup> Even though this assignment is  
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27 ambiguous because of the dynamic disorder present in most of the halide perovskites,<sup>55</sup> strictly  
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29 crystallographic criteria suggest the noncentrosymmetric structure to be the most favorable  
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31 one.<sup>56-57</sup>

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38 The crystal structures of the  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  ACI perovskites are unique among 2D  
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40 perovskites because they are characterized by a very unusual ordering of the GA and MA cations  
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42 which act as spacers between the perovskite layers. The GA/MA ordering leads to a doubling of  
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44 the unit cell along the *b*-axis relative to the ideal undistorted cell, which coincides with the  
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46 preferred growth direction of the crystals which adopt a needle-shaped morphology. The doubled  
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48 *b*-axis hosts two individual  $(\text{PbI}_6)^{4-}$  units, whereas the GA and MA cations form individual stacks  
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50 along the crystallographic *a*-axis to engulf a single  $(\text{PbI}_6)^{4-}$  unit. In order to accommodate the  
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52 ordering of the spacers, the perovskite layers deviate from their idealized tetragonal symmetry,  
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3 undergoing a strong octahedral tilting along the cation ordering axis (*b*-axis). Each layer  
4 compresses to engulf the compact MA spacer and expands to allow the incorporation of the  
5 bulky GA cation at the layer edges, forming rhombic and hexagonal channels, respectively in the  
6 process, Figure 3. The other two dimensions of the perovskite, along the *a* and *c* axes, remain  
7 relatively undistorted as there is no mismatch in the crystal packing of the organic cations. The  
8 MA cations that reside within the cuboctahedral perovskite cavities inside the layer adopt their  
9 usual orientation, by aligning along the crystallographic *c*-axis in a very similar arrangement to  
10 that observed in the 3D perovskite MAPbI<sub>3</sub>.  
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22 In order to better highlight the special features of the ACI perovskites it is important to  
23 compare them with the common structure archetypes. The general distinctive features of the DJ  
24 perovskites over the RP perovskites are: i) the number of cations spanning the layers is reduced  
25 to one in DJ perovskites vs. two in the RP perovskites; ii) the change in the relative arrangement  
26 of two adjacent layers which in the case of the DJ perovskites involves a shift by half a unit cell  
27 in one direction ( $\frac{1}{2}, 0$ ) or none at all (0, 0), but in RP perovskites involves a universal display of  
28 a half unit cell shift in both *a* and *b* crystallographic axes ( $\frac{1}{2}, \frac{1}{2}$ ).<sup>58</sup> In oxides, the crystal structure  
29 of DJ perovskites is strongly dependent on the size of the spacer cation and hinges between the  
30 two archetypes; the (0,0) modification (*P4/mmm* archetype) is obtained for large cations (Rb, Cs)  
31 which favor the occupation of the 8-coordinate sites between the layers, locking the layers on top  
32 of one another. Small cations (Li, Na) on the other hand, adopt lower coordination numbers  
33 resulting in the sliding of adjacent layer to the ( $\frac{1}{2}, 0$ ) configuration (*I4/mmm* archetype).<sup>59</sup> All  
34 members of the ACI (GA)(MA)<sub>n</sub>Pb<sub>n</sub>I<sub>3n+1</sub> homology adopt the latter ( $\frac{1}{2}, 0$ ) type of the DJ-like  
35 perovskite structure albeit in a lower symmetry modification which corresponds to the  
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3 “amphoteric” type of oxide DJ perovskites as obtained when 6-coordinated K is used as a spacer  
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5 and lies between the two archetypes.<sup>29, 59</sup>  
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8 The fact that the  $(GA)(MA)_nPb_nI_{3n+1}$  compounds adopt the offset layer structure is  
9 somewhat surprising given that both GA and MA are significantly larger than Cs.<sup>9</sup> An  
10 explanation to this may lie in the fact that the term “coordination” does not strictly apply to the  
11 organic cations and trying to compensate for this by means of H-bonding fails since the closest  
12  $N\cdots I$  distances are at  $\sim 3.6$  Å for both GA and MA implying only very weak hydrogen bonding.<sup>60</sup>  
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14 It is perhaps more sensible to assess this effect based on the shape of the two cations which have  
15 distinctive triangular (GA) and rod (MA) shapes and due to this “steric hindrance” the perovskite  
16 layers offset to accommodate both cations between the two layers in a close-packed arrangement.  
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18 Note that this DJ-like structural rearrangement observed in the ACI halide perovskites is  
19 necessary in order to maintain charge balance, since there is no conceivable charge redistribution  
20 between the  $M^{2+}$  metal and the  $A^+$  cation to satisfy the genuine DJ structure expressed by the  
21 hypothetical “ $(GA)(MA)_{n-1}Pb_nI_{3n+1}$ ” formula. By contrast, transition metal oxide DJ perovskites  
22 can maintain charge equilibrium and even interconvert to the RP structure simply by changing  
23 the oxidation state of the constituent  $M^{x+}$  metal (typically  $x = 4-5$ ) to compensate for the loss of  
24 the  $A^+$  cation.<sup>34</sup> The close-packing of the GA and MA cations can be seen when the arbitrary  
25 “coordination” polyhedra around the GA (cutoff distance 4.8 Å) and MA (cutoff distance 4.2 Å)  
26 cation are drawn, centered on the carbon atom of each cation, Figure 3. Both cations are 8-  
27 coordinate with MA lying in the center of a compressed square prism and GA in the center of an  
28 expanded gyrobifastigium. The parallelogram equatorial planes of the two polyhedra reflect  
29 clearly the distortion of the perovskite lattice to accommodate the two cations. The equatorial  
30 plane of both cations is defined by two parallel vertices that coincide with the crystallographic  
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3 axes along the  $a$ -direction and another two along the  $b$ -direction. Along  $a$ -axis the vertices  
4 coincide with unit cell parameter ( $\sim 6.3$  Å), whereas along the  $b$ -axis the vertices deviate with the  
5 one around GA expanding to  $\sim 7.3$  Å whereas the one around MA gets compressed to  $\sim 5.2$  Å. The  
6 geometrical “sum” of these two octahedra has proper dimensions to allow for the doubling of the  
7 perovskite layer along the  $b$ -axis ( $\sim 12.5$  Å) and it is probably responsible for the offset of the  
8 adjacent layers.  
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11 Because of their specific characteristics, the crystal structures of the ACI perovskites are  
12 distinctively different from the corresponding RP perovskites. Using the RP  $(\text{BA})_2(\text{MA})_n$   
13  $_{1}\text{Pb}_n\text{I}_{3n+1}$  series as a reference example,<sup>6</sup> the most distinctive differences can be summarized as  
14 follows: i) RP perovskites exhibit a significant distortion in both  $a$  and  $b$  crystallographic  
15 directions owing to the distortive nature of the bulky BA spacers which exert a strong disruptive  
16 force at the perovskite edges. In ACI perovskites, however, the combination of the MA/GA  
17 cations which pack tightly between the layers causes the distortion to be minimized in only one  
18 direction. Using the crystallographic nomenclature (Glazer<sup>61</sup> in parenthesis or Aleksandrov<sup>53</sup> in  
19 square brackets), the individual layers in the BA series is characterized by a  $(\bar{a}^0 a^0)$  [ $\Phi 0 \Phi$ ]  
20 tilting mode whereas the GA/MA series by a  $(a^+ a^0 a^0)$  [ $\Psi 0 0$ ] mode. Remarkably, none of these  
21 two series has any significant distortion along the stacking direction, unlike the corresponding  
22 PEA series (PEA is phenylethylammonium)<sup>8, 62</sup> which shows a tilting preference along the  
23 stacking axis adopting a  $(a^0 a^0 a^+)$  [ $0 0 \Psi$ ] tilting mode. ii) As a result of the more tidy packing of  
24 the cations, ACI perovskites are more symmetric as reflected in the shape of the unit cell [ $a \times 2a$   
25  $\times 2(a_n+x)$ ] which is closer to the  $\alpha$ -phase of the 3D perovskite as opposed to the RP perovskites  
26 [ $\sqrt{a} \times \sqrt{a} \times 2(a_n+x)$ ]. The latter are better described as a derivative of the  $\beta$ -MAPbI<sub>3</sub> phase at  
27 room temperature.  
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3 **Optical Properties.** It is very interesting to investigate in the new structure types in 2D halide  
4 perovskites how these small structural changes affect the electronic structure of the material *vis-*  
5 *à-vis* the RP phases and consequently their photophysical properties. Figures 4a-c shows the  
6 absorption spectra of the (GA)(MA)<sub>n</sub>Pb<sub>n</sub>I<sub>3n+1</sub> perovskites (n = 1-3). The spectra of all three  
7 compounds exhibit a progressive decrease in the bandgap starting from  $E_g = 2.27$  eV for n = 1 to  
8  $E_g = 1.99$  eV for n = 2 and  $E_g = 1.73$  eV for n = 3. The bandgap value is estimated by  
9 extrapolating the high-energy edge to the energy axis, since the presence of excitonic peaks in all  
10 spectra precludes the observation of a clear band edge. Similar to the RP perovskites, the  
11 intensity of the excitonic peaks also decreases with increasing n in ACI perovskites as a  
12 consequence of the decrease in the dielectric confinement.<sup>6</sup> However, the absorption edge and  
13 the exciton peak position is red shifted in ACI perovskites when compared to the RP perovskites.  
14 This is also reflected in the color of the (GA)(MA)<sub>n</sub>Pb<sub>n</sub>I<sub>3n+1</sub> compounds which changes from red  
15 (n = 1) to dark red (n = 2) to black (n = 3), whereas the more established BA-based RP series  
16 display a corresponding color change from orange (n = 1) to red (n = 2) to dark red (n = 3),  
17 Figures 4a-c.

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A plausible, but not conclusive, explanation for this behavior is the symmetry (degree of distortion) in the corresponding perovskites.<sup>63</sup> As mentioned above, the ACI perovskites are distorted only along one dimension (the GA/MA ordering axis), whereas the RP perovskites are distorted along both directions in the *ab*-plane. The higher symmetry of the ACI perovskites is clearly reflected in the corresponding Pb-I-Pb angles which show the tilting along the *a*-axis to be marginal (176-180°), along the *b*-axis large (~160°) and intermediate along the stacking *c*-axis (165-167°). The trend is markedly different from the RP perovskites which see a more uniform deformation with the corresponding Pb-I-Pb angles ranging between 165-170° for both the *ac*-

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3 plane and the stacking  $b$ -axis.<sup>6</sup> This symmetry argument, stating that the less distorted crystal  
4 structure will have the narrowest bandgap that applies to the 3D halide perovskites,<sup>10</sup> likely  
5 applies to the 2D perovskites as well, with the ACI and RP perovskites being the primary  
6 examples. In order to better illustrate the bandgap reduction effect, the absorption edges of the  $n$   
7 = 1 members of the ACI, RP and  $\langle 110 \rangle$ -sliced perovskites are plotted in Figure 4d. The observed  
8 trend reinforces the symmetry argument since it shows that the most distorted structure of the  
9  $\langle 110 \rangle$ -sliced perovskite  $\text{GA}_2\text{PbI}_4$  ( $P2_1/n$ ,  $E_g = 2.49$  eV)<sup>40</sup> has by far the widest bandgap. This is  
10 due to the larger distortion and the dihedral angle dependence introduced by the  $\langle 110 \rangle$  cleavage  
11 of the perovskite sheets.<sup>11</sup> This can be compared to the regular absorption of the less distorted  
12 RP perovskite  $\text{BA}_2\text{PbI}_4$  at  $E_g = 2.35$  eV<sup>6</sup> and the  $\text{GAMAPbI}_4$  ACI perovskite at  $E_g = 2.27$  eV.  
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27 The reason that the symmetry argument discussed above may not hold in full in the 2D  
28 perovskites is that other factors such as the contribution of spacer cations to the dielectric  
29 confinement or their close proximity of the perovskite layers can be significant. As first pointed  
30 out by Ishihara,<sup>64</sup> the dielectric constant of the spacer can dramatically influence the excitons in  
31 in 2D perovskites pinpointing the effect of conjugated organic molecules to the binding energy of  
32 the confined exciton. The photo-physical puzzle of the 2D materials becomes even more  
33 complex if one considers that the precise determination of the band edge continuum relative to  
34 the exciton energy level may be challenging,<sup>3, 65</sup> and that the mechanism of the exciton  
35 expression also shows a strong temperature dependence.<sup>66</sup> Nevertheless, on first approximation,  
36 the excitonic emission as this gets expressed using photoluminescence (PL) spectroscopy does  
37 not seem to be affected by these considerations, Figure 5.  
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53 The PL spectra of the  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  ACI perovskite family (Figure 5) follows a  
54 similar trend as the absorption spectra, with the PL emission wavelength increasing with  
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3 increasing n. The red shift in absorption observed for the ACI perovskites, relative to the RP  
4 perovskites, holds firmly in the PL spectra as well. The marked difference between the spectra of  
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6 the two 2D families is that the ACI perovskites show significantly reduced PL emission intensity  
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8 relative to the RP series under comparable excitation conditions suggesting that the effect of the  
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10 dielectric environment due to the conjugated nature of the GA cations or the close proximity  
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12 between the perovskite layers has a significant effect. Although the present work is not an  
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14 exhaustive study of the optical properties of the new ACI perovskites, it is already obvious that  
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16 the properties of all 2D halide perovskites are significantly influenced by subtle structural  
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18 changes and thus offer a wide field for further investigations.  
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24 **Band structure.** The electronic band structure of the  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  perovskites ( $n = 1-3$ )  
25 was determined by means of Density Functional Theory (DFT) calculations. The calculations  
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27 indicate that both the  $n = 1$  and  $n = 3$  members are direct bandgap semiconductors at the R point  
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29 of the Brillouin zone whereas the  $n = 2$  member has a slightly indirect bandgap at the S point,  
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31 Figure 6a. The  $n = 2$  member shows a slight deviation from the typical direct bandgap behavior,  
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33 observed in halide perovskites because of strong Rashba splitting caused by the  
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35 noncentrosymmetric nature of its structure (Figure S1). The calculated bandgaps are  
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37 underestimated within their typical margins at this level of theory but they nicely agree with the  
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39 experimental trends for the ACI  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  perovskites of  $E_g = 1.12$  eV ( $n = 1$ ),  $E_g =$   
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41  $0.75$  eV ( $n = 2$ ) and  $E_g = 0.12$  eV ( $n = 3$ ). Noteworthy, at the same level of calculation, the  
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43 corresponding bandgaps for the RP  $(\text{BA})_2(\text{MA})_{n-1}\text{Pb}_n\text{I}_{3n+1}$  perovskites amount to  $E_g = 1.17$  eV ( $n$   
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45  $= 1$ ),  $E_g = 0.74$  eV ( $n = 2$ ) and  $E_g = 0.49$  eV ( $n = 3$ ) again predicting the experimental trend (with  
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47 the exception of  $n=2$ ).  
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3 A remarkable feature observed in the ACI perovskites comes from the fact that they  
4 show a small but significant dispersion along the perovskite layer stacking direction (Figure 6a  
5 and Table S7; along W-T for  $n = 1$  and Y- $\Gamma$  for  $n = 2$ ), suggesting that the structures of the ACI  
6 perovskites have a weak but noticeable 3D character. The effect is greater at the valence band  
7 maximum (VBM) than at conduction band minimum (CBM; Table S7) and is likely due to the  
8 short spacing between the layers ( $\sim 3.1$  Å) that is comparable with the Pb-I bonding within the  
9 perovskite layers ( $\sim 3.2$  Å). In fact, the short spacing allows for additional anti-bonding  
10 interaction between iodine p-orbitals (Figure 6b), leading to a greater destabilization of the VBM  
11 at the edge of the Brillouin zone. Interestingly, the bands stop being dispersive between the  
12 layers for  $n = 3$  ( $< 1$  meV) resulting in the typical 2D perovskite picture which has nearly flat  
13 bands along the layer stacking direction (e.g.  $< 1$  meV for the  $n = 1-3$  RP  $(\text{BA})_2(\text{MA})_{n-1}\text{Pb}_n\text{I}_{3n+1}$ ).  
14 However, the reasons for the almost vanishing dispersion are different in the two cases. In the  
15 typical 2D RP perovskites the interlayer distance is large leading to a vanishing electronic  
16 coupling along the stacking direction. In addition, for the  $n = 3$  ACI perovskite, the VBM  
17 becomes localized on the middle perovskite layer with no weight on the iodides pointing towards  
18 the spacing layer (Figure 6b). This localization, in turn, leads to the absence of inter-perovskite  
19 layer electronic coupling. Interestingly, the CBM for the  $n = 3$  localizes on the two outer  
20 perovskite layers. By contrast, in the  $n = 1$  perovskite both VBM and CBM reside on the same  
21 unique perovskite layer not allowing the charges to be efficiently separated. The localized  
22 density of states for the  $n = 2$  ACI perovskite evidences a distinctive feature related to its  
23 noncentrosymmetric  $Bmm2$  space group and the VBM and CBM are forced to localize on each  
24 individual layer finding themselves in a state of “charge-frustration”.  
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3 In order to assess the effect of the spacer dielectric constant on the dielectric confinement  
4 of the ACI perovskites, we calculated the dielectric constant of the  $(GA)(MA)_nPb_nI_{3n+1}$   
5 perovskites ( $n = 1$  and  $3$ ) of this study to compare to those of the RP  $(BA)_2(MA)_{n-1}Pb_nI_{3n+1}$   
6 perovskites ( $n = 1$  and  $3$ , Figure S2).<sup>67-68</sup> We avoid the inclusion of the  $n = 2$  members because  
7 the permanent dipole related to the lack of inversion symmetry mentioned above bias the  
8 calculation. The calculated dielectric profiles indicate that the dielectric contrast difference  
9 between the inorganic and the spacer layers is significantly reduced for the ACI perovskites by a  
10 factor of 2 compared to those obtained for the RP perovskites. Using a previously proposed  
11 composite approach,<sup>69</sup> we demonstrate that the higher dielectric constant in the spacer layer in  
12 ACI perovskites can be attributed to the leakage of electron density from the perovskite layers  
13 due to the shorter interlayer spacing, as the contribution of the more polarizable GA/MA pairs is  
14 only marginally larger than that of the  $(BA)_2$  bilayers (Figure 2d). The reduction of the dielectric  
15 confinement effect is expected to reduce the exciton binding energy. This trend holds universally  
16 throughout the two perovskite families in which the dielectric constants of the materials increase  
17 progressively to reach the maximum value of the dielectric constants found in the  $n = \infty$  member  
18 ( $MAPbI_3$ ).

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41 **Thin film fabrication and morphology.** For solar cell applications, we focused on the  
42 compound with the smallest bandgap,  $GAMA_3Pb_3I_{10}$  ( $n = 3$ ). First, thin films of this compound  
43 were prepared from 10:1 DMF:DMSO solutions. The synthesized compounds readily dissolve in  
44 such solvents, yielding a clear bright yellow solution. It was found that a typical post-annealing  
45 method yields a very rough, dull-colored film with a root-mean-square (rms) roughness of 37  
46 nm, Figure 7a. The pinholes found in this type of film are unfavorable for planar solar cell device  
47 architectures, creating undesired contacts between the two electrodes that results in poor device  
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3 performance.<sup>70</sup> To improve the film quality, we applied the previously reported solvent-  
4 engineering method where anti-solvent, specifically chlorobenzene, is dripped during the  
5 spinning of the substrate to expedite the solvent removal process and subsequently promotes  
6 faster perovskite crystallization.<sup>71-72</sup> This method enables precise control of the perovskite  
7 crystallization rate by changing the delay time before the commencement of the spin-casting  
8 process and the anti-solvent dropping.  
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11 Here we investigated the optimal crystallization rate for  $\text{GAMA}_3\text{Pb}_3\text{I}_{10}$  by varying the  
12 delay time between 3 s and 50 s. The obtained films exhibit a desirable compact morphology  
13 with nm-scale crystallites, a dramatic improvement from the films without the solvent treatment.  
14 We find that 20-30 s delay times yield the smoothest, most compact films. Upon the introduction  
15 of anti-solvent drip, the film surface rms roughness decreases markedly down to 10 nm for 10-20  
16 s delay times, beyond which it begins to increase again and eventually reaches 35 nm at 50 s,  
17 Figure 7b. The PXRD of these films are shown in Figure 7c. All the films were polycrystalline,  
18 consistent with the Bragg diffraction rings in the 2D GIWAXS data (Figure S3). Unlike RP  
19 perovskites,<sup>2, 4, 8</sup> the present films from ACI perovskites do not orient vertically, presumably due  
20 to the shorter spacing between the perovskite layers provided by GA in comparison to BA  
21 cations.  
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44 Even though the perovskite slab orientation on the substrate is still suboptimal, we  
45 fabricated solar cells with high efficiency. We constructed planar device structures sandwiched  
46 between a PEDOT:PSS hole transport layer and a PCBM electron transport layer, Figure 8a,  
47 since the desirable vertical growth of the layered perovskites is more favorable on flat substrates  
48 for efficient charge transport.<sup>2</sup> The perovskite layer was deposited using the fast-crystallization  
49 method with anti-solvent dripping, as described above. Following the trend shown in the AFM  
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3 images of the films, Figure 6a, which show the rms roughness of the films steadily decreasing  
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5 down to ~20s anti-solvent dripping delay time and then increasing again after the 30s delay  
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8 mark, we fabricated devices at the same dripping delay time intervals to study the effect of film  
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10 morphology on the device performance. Here the delay time is defined as the time between the  
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12 commencement of the spin-casting process and the dripping of the anti-solvent while the  
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14 substrate is spinning. The devices without the solvent treatment were not functional because of  
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16 the high roughness and protruding features on the rough perovskite film which create shorting  
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18 pathways. We observed a dramatic change in device parameters depending on when the anti-  
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20 solvent is dropped. As expected, there is a distinct correlation between the device performance  
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22 and the perovskite film smoothness and compactness. At very short delay times, low  
23  
24 photocurrents and low  $V_{oc}$  are observed, which improve upon increasing the anti-solvent delay  
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26 time, Figure 8.  
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32 Remarkably, a significant improvement in the overall performance is observed at 10-20  
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34 sec delay due to the formation of the compact, smooth film morphology. In particular, at 20 s  
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36 delay time, a high  $V_{oc}$  of ~1V, high  $J_{sc}$  of 9.84 mA/cm<sup>2</sup>, and an impressively high FF of 79.68%  
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38 are obtained. The high  $V_{oc}$  illustrates an excellent interface between the perovskite layer and the  
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40 charge extraction layers. Intriguingly, while 2D perovskites typically suffer from low FF due to  
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42 the relatively higher charge recombination rate than their 3D counterparts, here we obtain a  
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44 superior FF, which we attribute to the high-quality film morphology with full surface coverage  
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46 and minimal pinholes. These qualities are in good agreement with previous studies on MAPbI<sub>3</sub>  
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48 where GA was used as an additive.<sup>73</sup> The main difference between the devices fabricated from  
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50 the bulk materials as described here vs. devices made by mixing the constituent salts as described  
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52 by Marco et al.<sup>73</sup> can be seen from the optical absorption spectra and the PXRD patterns of the  
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3 films (Figures S3 and S4). Our data clearly identify the active solar absorber to be the title 2D  
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5 compound, whereas the additive approach yields MAPbI<sub>3</sub> as the active absorber.<sup>73</sup> Our results  
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7 suggest that the ACI perovskites are very promising in giving a competitive device efficiency  
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9 even without the benefits of preferred orientation,<sup>2,4</sup> which is an obvious path towards improving  
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11 device performance in the future.  
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15 The present solar cells also show high reproducibility with an average PCE from 10  
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17 devices  $6.69 \pm 0.47\%$ . For longer anti-solvent delay times, the device performance begins to  
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19 decrease, as evidenced by large drops in  $V_{oc}$  and FF on going from 20 sec to 50 sec (Table 4).  
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21 This may be caused by the increased surface inhomogeneity and roughness as crystallites begin  
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23 to aggregate and form nanostructures compromising the compactness of the films. It is, however,  
24  
25 interesting that the photocurrent did not change significantly for longer delay times, likely  
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27 because the intrinsic film crystallinity remains unaltered regardless of the delay time.  
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32 To ensure fabrication of high efficiency solar cells, it is essential to optimize the light  
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34 absorber thickness, since the light harvesting ability and carrier diffusion length must be  
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36 balanced for optimum solar cell efficiency. Thus, we conducted a systematic study of device  
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38 efficiency as a function of precursor concentration, which in turn determines the perovskite  
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40 thickness and find an optimized condition at 30 mg in 110  $\mu$ L solvent mixture (Figure S3).  
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42 Compared to BA-based  $n = 3$  cells, the photocurrent generated in this GA-based  $n = 3$  devices is  
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44 comparatively low, likely due to non-optimally oriented nature of the 2D GAMA<sub>3</sub>Pb<sub>3</sub>I<sub>10</sub>. Work is  
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46 in progress to further engineer the vertical orientation of the microstructure to further improve  
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48 device performance.  
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## 52 53 54 CONCLUSIONS

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3 A new family of 2D halide perovskites of the formula  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_n\text{Pb}_n\text{I}_{3n+1}$  can be  
4 created which contains alternating cations in the interlayer space (ACI), by employing  
5 guanidinium cations as spacers. The red crystals of  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)\text{PbI}_4$  ( $n = 1$ ) have an  
6 optical gap of 2.27 eV; dark red crystals of  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_2\text{Pb}_2\text{I}_7$  ( $n = 2$ ) have a 1.99 eV  
7 optical gap, and black crystals of  $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_3\text{Pb}_3\text{I}_{10}$  ( $n = 3$ ) have a bandgap of 1.73 eV.  
8 These materials have narrower bandgaps in comparison to typical RP perovskites, exhibiting a  
9 clear red shift in their optical gaps by 80, 90 and 230 meV, respectively for the corresponding  $n =$   
10 1-3 members. We attribute the reduced bandgap of the ACI perovskites to their less distorted  
11 crystal structure, behaving in an analogous manner to the 3D halide perovskites as the A-cation  
12 changes from Cs to FA. Theoretical calculations successfully confirm this trend providing further  
13 insights in the dielectric confinement of these QW electronic systems, and suggesting a small  
14 exciton binding energy, which is beneficial for charge-transport related applications. Our initial  
15 attempts to employ these compounds as photo-absorbers in planar solar cells for the higher  
16 member of the ACI perovskites,  $\text{GAMA}_3\text{Pb}_3\text{I}_{10}$  with the smallest bandgap within the present  
17 series, have yielded solar cell devices with a maximum  $\eta = 7.26\%$  power conversion efficiency  
18 due to an impressive FF of  $\sim 80\%$ . The superior optoelectronic properties of the 2D ACI  
19 perovskites suggest that this new class of compounds can advance photovoltaic research on 2D  
20 halide perovskites, offering the possibility of breaching the 15% efficiency threshold.  
21 Previously, we reported that the photo-physics of thin Ruddlesden-Popper perovskites films with  
22  $n > 2$  are dominated by lower energy states associated with the local intrinsic electronic structure  
23 of the edges of the perovskite layers. These states appear to provide a direct pathway for  
24 dissociating excitons into longer-lived free-carriers that significantly enhance optoelectronic  
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3 device performance. The question arises as to whether the ACI perovskites also exhibit similar  
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5 edge states and will be the subject of future investigations.  
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### 8 **Supporting Information**

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10 Additional DFT plots for  $\text{GAMA}_2\text{Pb}_2\text{I}_7$  highlighting the noncentrosymmetric features (Rashba  
11  
12 splitting) of the compound, dielectric constant calculations, and PXRD and GIWAXS patterns of  
13  
14  $\text{GAMA}_2\text{Pb}_2\text{I}_7$  and  $\text{GAMA}_3\text{Pb}_3\text{I}_{10}$  are provided in the Supporting Information. Detailed  
15  
16 crystallographic tables and crystallographic data in .cif format can be found as supplementary  
17  
18 materials. This material is available free of charge via the Internet at <http://pubs.acs.org>.  
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### 28 **Author Contributions**

29  
30  
31 #These authors contributed equally to this work.  
32

### 33 **Notes**

34  
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36 The authors declare no competing financial interest.  
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## Figure Captions

**Figure 1.** (a) Representative SEM images of  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  ( $n = 1-3$ ) crystals showing a plate-like crystal morphology. The plates are irregular parallelepipeds growing preferentially along one dimension. The scale bars represent a  $50\mu\text{m}$  length. (b) High resolution synchrotron X-ray data (11-BM, APS,  $\lambda = 0.517040 \text{ \AA}$ ) for  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  ( $n = 1-3$ ). The experimental data are in excellent agreement with the theoretical patterns determined by single-crystal X-ray diffraction analysis. The impurity observed in the  $n = 1$  perovskite that grows on the surface of the crystal was identified to arise from the  $n = 2$  member and amounts to  $\sim 10\%$  of the sample.

**Figure 2.** View of the unit cells of the  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  ( $n = 1-3$ ) perovskites along (a) the crystallographic  $b$ - and along (b) the crystallographic  $a$ -axis highlighting the ordered crystal packing of the GA and MA cations between the perovskite layers

**Figure 3.** (a) Projected view of a supercell of  $(\text{GA})(\text{MA})_3\text{Pb}_3\text{I}_{10}$  along the crystallographic  $a$ -axis emphasizing on the polyhedral voids between the perovskite layers. (b-c) The “coordination” polyhedra of the GA and MA cations. (b) GA resides in the barycenter of a gyrobifastigium and (c) MA resides in the center of a square prism cavity. (d-f) The crystal packing of the respective polyhedra. (d) Packing of the GA cations along the  $a$ -axis. (e) Packing of GA and MA along the  $b$ -axis. (f) Side view of the packing of MA cations along the  $a$ -axis.

**Figure 4.** (a-c) Optical absorption spectra of the  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  ( $n = 1-3$ ) perovskites. (d) Selected absorption spectra of  $n = 1$  member of the ACI perovskite  $(\text{GA})(\text{MA})\text{PbI}_4$ , the RP perovskite  $(\text{BA})_2\text{PbI}_4$  and the (110)-cleaved perovskite  $(\text{GA})_2\text{PbI}_4$  highlighting the importance of the perovskite structure-type on the optical properties of the materials.

**Figure 5.** (a-c) Steady-state PL spectra and (d) graphical representation of the  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  ( $n = 1-3$ ) ACI perovskites (solid lines) and their comparison with the corresponding  $n$ -members of the  $(\text{BA})_2(\text{MA})_{n-1}\text{Pb}_n\text{I}_{3n+1}$  series of RP perovskites.

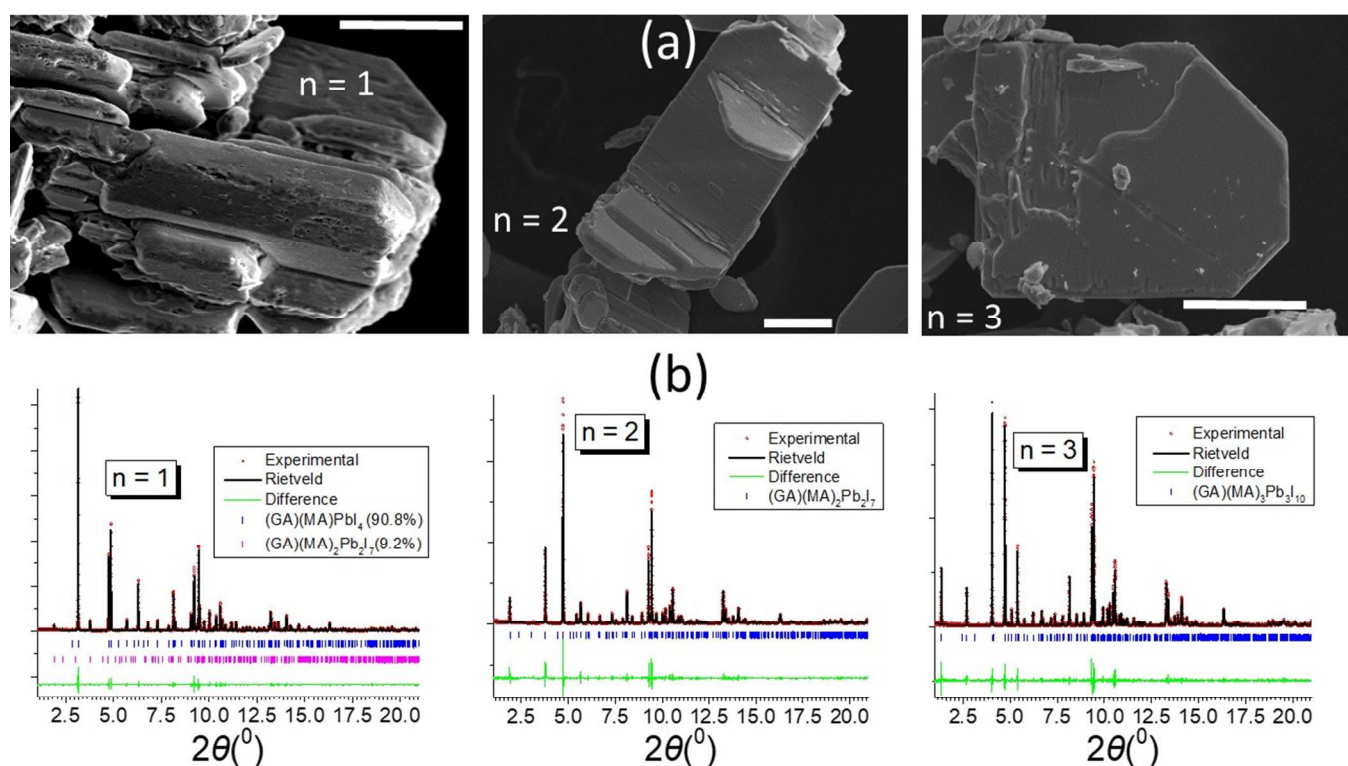
**Figure 6.** Electronic structure of the  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  ( $n = 1-3$ ) perovskites. (a) Electronic band structure of the  $n = 1-3$  members highlighting the progressive narrowing of the bandgap and the splitting of the band extrema as the number of 2D layers increases. (b) The localized density of states around the conduction band minimum (CBM) and the valence band maximum (VBM), illustrating the propensity of the terminal 2D layers to host the CBM and the central 2D layers to stabilize the VBM.

**Figure 7.** (a) AFM images of solution-processed thin films of  $(\text{GA})(\text{MA})_3\text{Pb}_3\text{I}_{10}$  as a function of delay time for anti-solvent chlorobenzene (CB) dripping. The scale bar is  $2 \mu\text{m}$ . (b) change in

surface roughness with increasing CB drip delay time. The size of the AFM image is 10  $\mu\text{m}$  x 10  $\mu\text{m}$ , and (c) PXRD of the associated films, illustrating little influence of the anti-solvent delay time on the film crystallinity and orientation.

**Figure 8.** (a) Planar heterojunction solar cell structure employing  $(\text{GA})(\text{MA})_3\text{Pb}_3\text{I}_{10}$  as a light absorber. (b) J-V curves of  $(\text{GA})(\text{MA})_3\text{Pb}_3\text{I}_{10}$  as a function of delay time for anti-solvent chlorobenzene (CB) dripping, and (c) the corresponding plots  $J_{\text{sc}}$ ,  $V_{\text{oc}}$ , FF and power conversion efficiency as a function of delay time for anti-solvent dripping.

## Figures



**Figure 1**

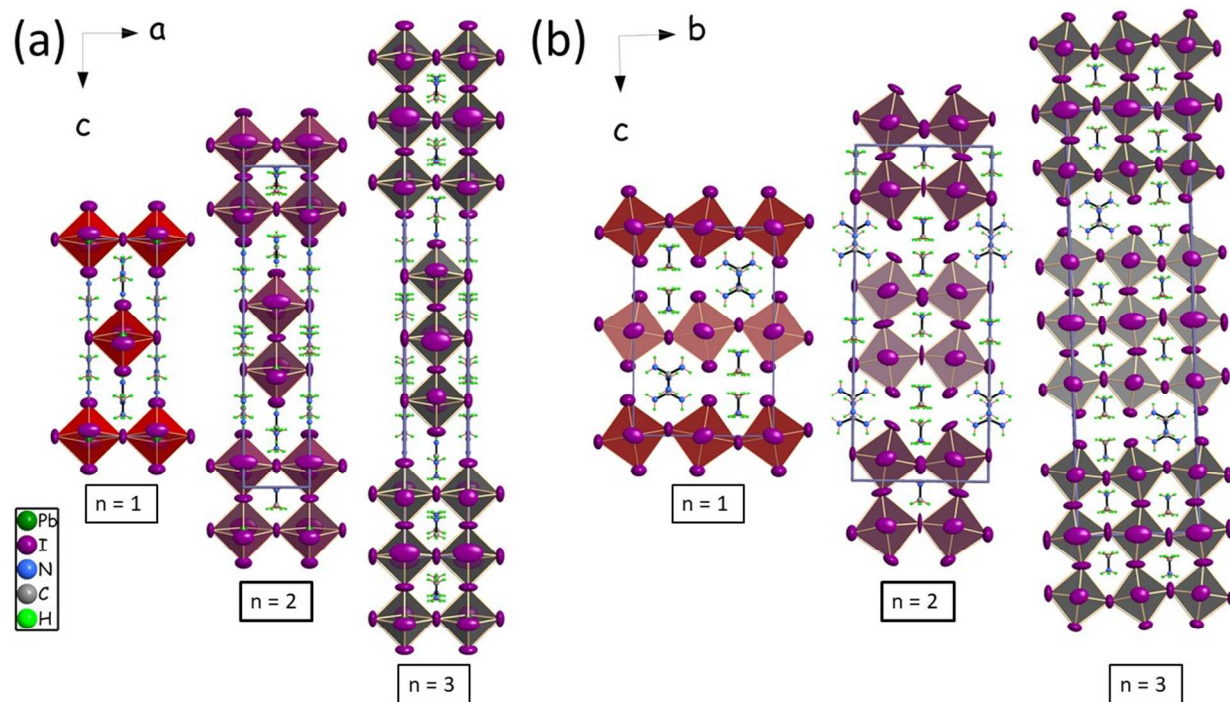


Figure 2

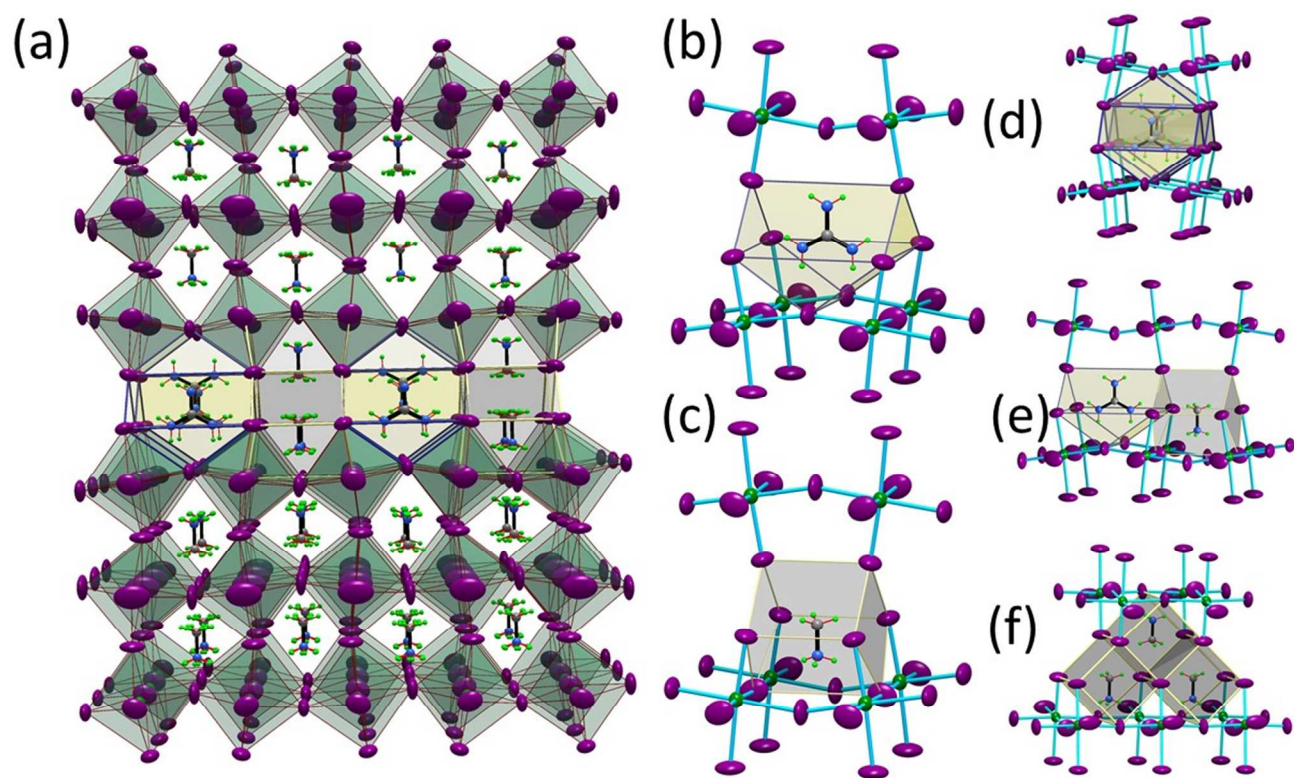


Figure 3



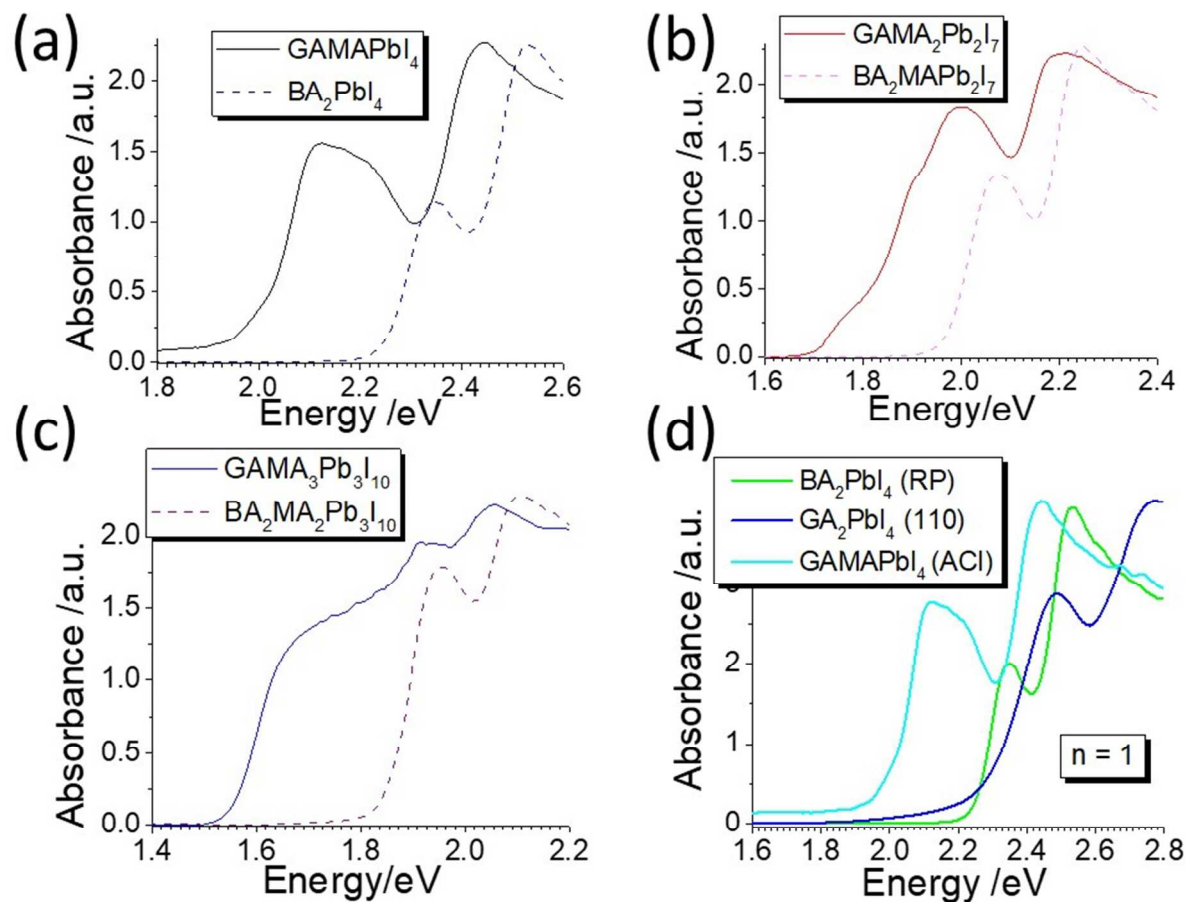


Figure 4

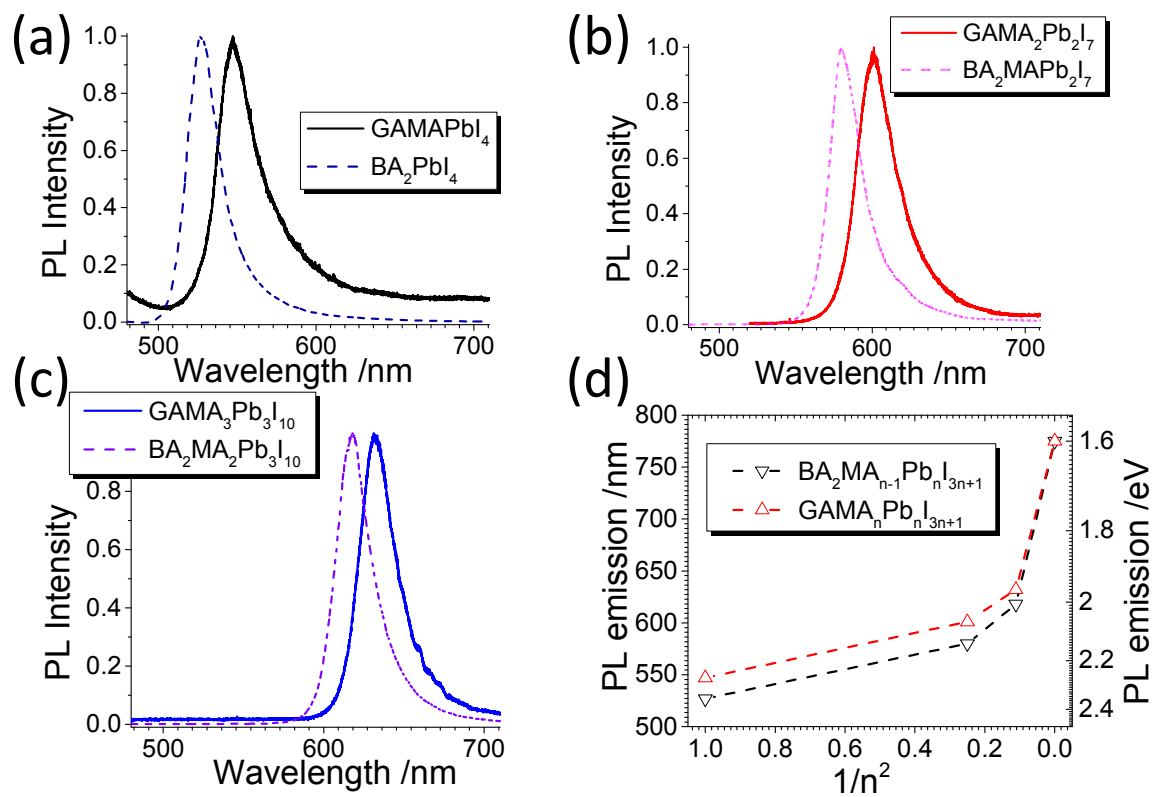


Figure 5

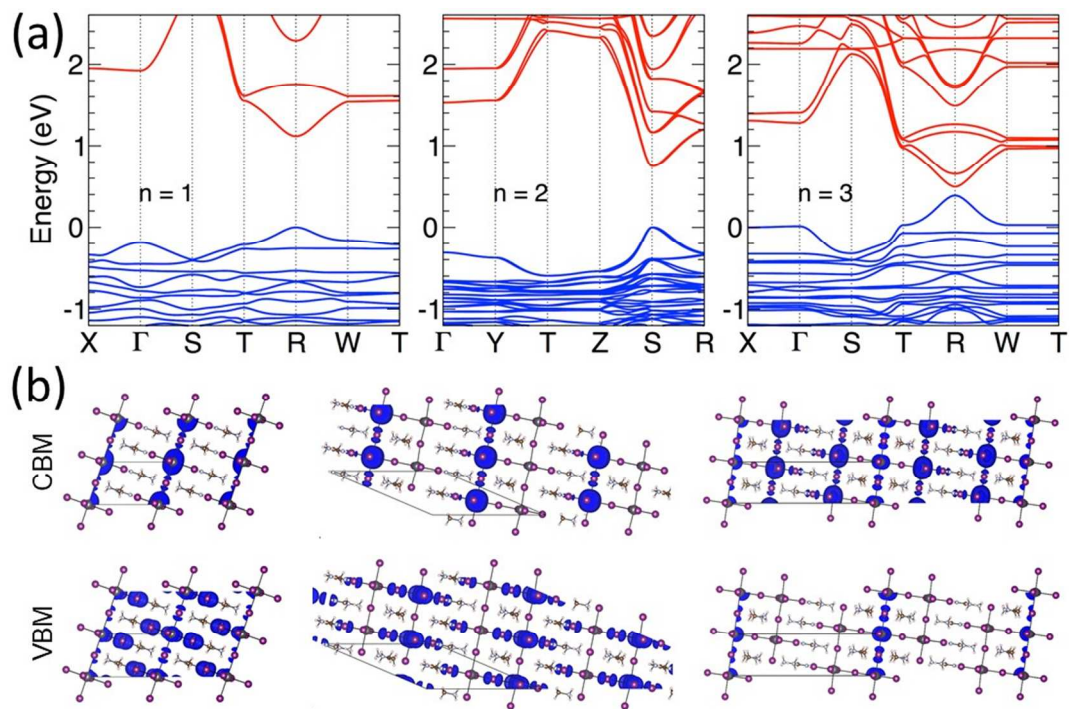
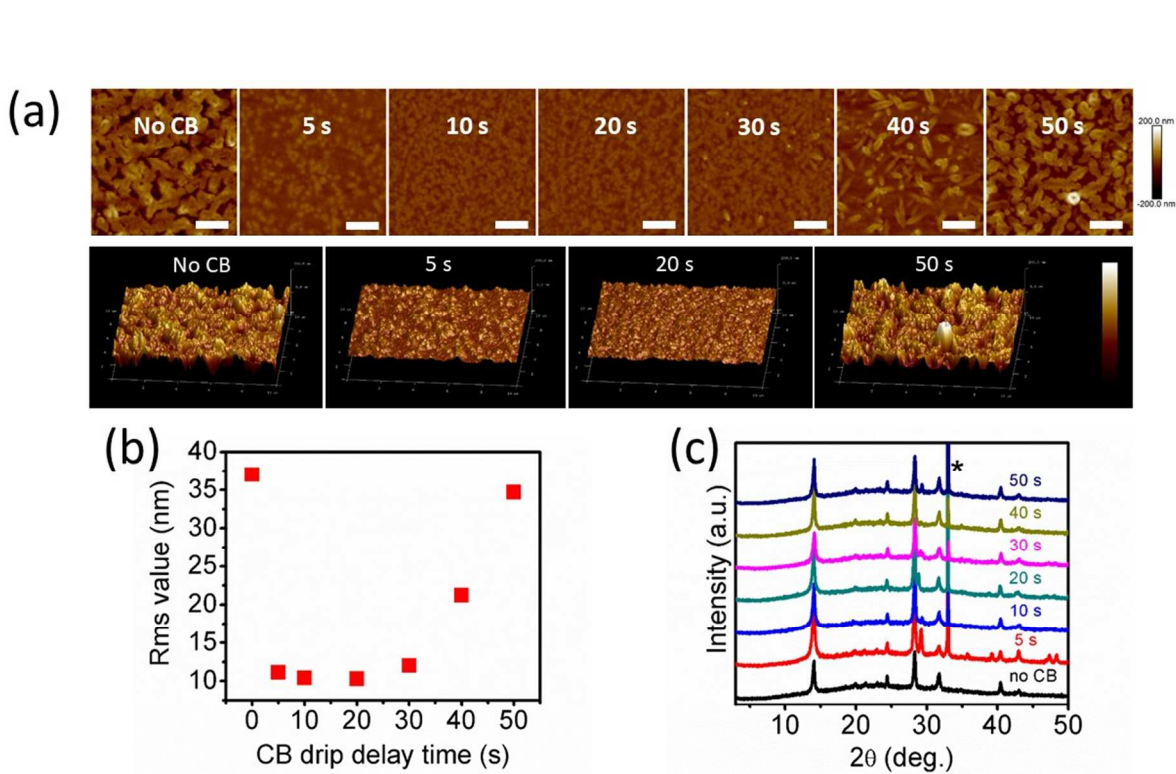


Figure 6



**Figure 7**

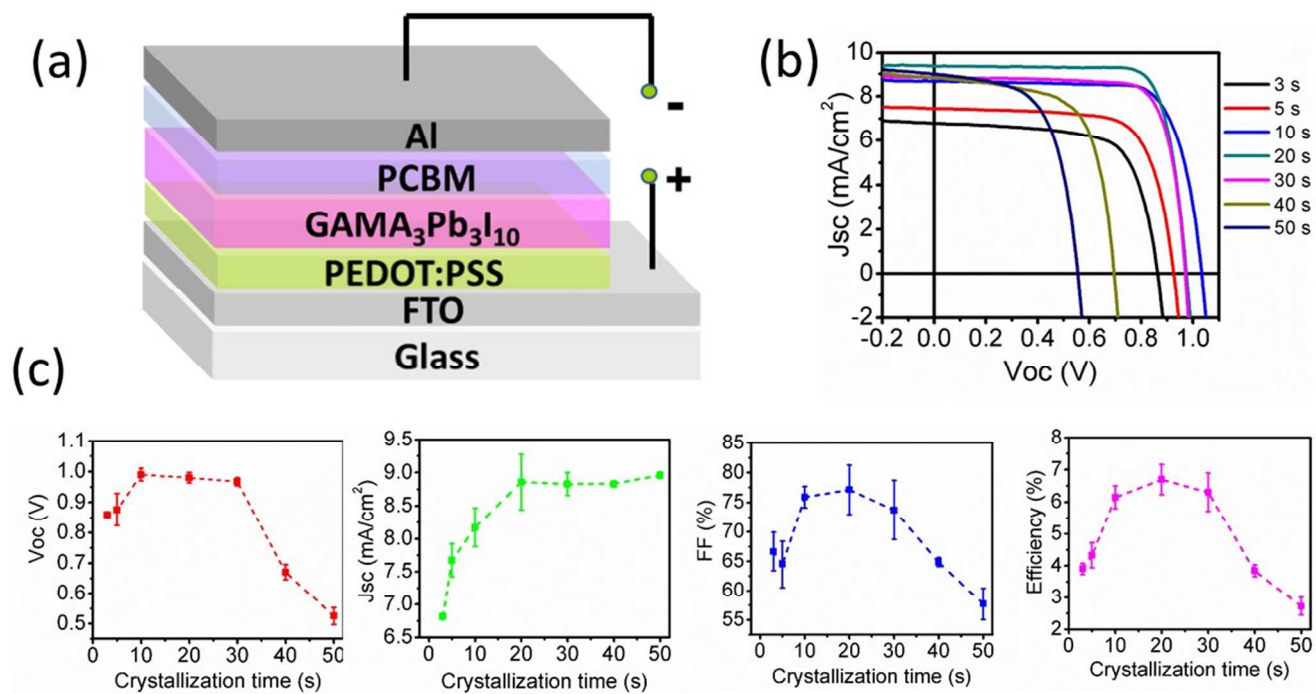


Figure 8

**Table 1.** Structural configurations of the three types of <100> 2D perovskites.

	RP	DJ	AV	ACI
Formula	$(A'A)_{n+1}B_nX_{3n+1}$	$A'A_{n-1}B_nX_{3n+1}$	$(Bi_2O_2)A_{n-1}B_nX_{3n+1}$	$(A'A)_{n+1}B_nX_{3n+1}$
Stacking sequence	$[(AX)(ABX)_n]$	$[(A')(A_{n-1}BX)_n]$	$[(Bi_2O_2)(A_{n-1}BX)_n]$	$[(AX)(ABX)_n]$
Centering of perovskite slabs <sup>a</sup>	$I(\frac{1}{2}, \frac{1}{2}, \frac{1}{2})$	$P(0,0,0)$	$I(\frac{1}{2}, \frac{1}{2}, \frac{1}{2})$	$A/B/C(\frac{1}{2}, 0, \frac{1}{2})$
$n = 3$ exemplar	$Sr_4Ti_3O_{10}$	$KCa_2Nb_3O_{10}$	$(Bi_2O_2)SrTa_2O_9$ <sup>b,c</sup>	$(GA)(MA)_3Pb_3I_{10}$

<sup>a</sup> in the aristotype, *ie.* ignoring octahedral tilts<sup>b</sup> The  $n = 2$  is chosen for clarity; for the  $n = 3$  member see reference <sup>27</sup><sup>c</sup> Reference <sup>74</sup>

**Table 2.** Crystal data and structure refinement for  $\text{GAMA}_n\text{Pb}_n\text{I}_{3n+1}$  ( $n = 1-3$ ) at 293 K.

Formula	$\text{GAMA}\text{PbI}_4$	$\text{GAMA}_2\text{Pb}_2\text{I}_7$	$\text{GAMA}_3\text{Pb}_3\text{I}_{10}$
FW	807.0	1426.9	2046.9
Temperature (K)	293		
Wavelength	0.71073 Å		
Refinement method	Full-matrix least-squares on $F^2$		
Crystal system	orthorhombic		
Space group	<i>Imma</i>	<i>Bmm2</i>	<i>Imma</i>
Unit cell dimensions (Å)	a = 6.4286(6) b = 12.4577(9) c = 18.8258(13)	a = 6.3729(4) b = 12.5435(8) c = 31.376(2)	a = 6.3520(7) b = 12.4378(9) c = 43.970(3)
Volume (Å <sup>3</sup> )	1507.7(2)	2508.2(3)	3473.8(5)
Z	4	4	4
$\rho_{\text{calc}}$ (g/cm <sup>3</sup> )	3.5551	3.7788	3.9138
$\mu$ (mm <sup>-1</sup> )	19.349	22.017	23.395
F(000)	1392	2424	3464
Crystal size (mm <sup>3</sup> )	0.1111 x 0.0225 x 0.0167	0.0511 x 0.179 x 0.0100	0.0733 x 0.0372 x 0.0193
$\theta$ range (°)	3.27 to 29.23	2.6 to 29.27	2.78 to 29.29
Index ranges	-8 ≤ h ≤ 8 -17 ≤ k ≤ 16 -25 ≤ l ≤ 25	-8 ≤ h ≤ 8 -17 ≤ k ≤ 17 -42 ≤ l ≤ 42	-8 ≤ h ≤ 8 -17 ≤ k ≤ 16 -57 ≤ l ≤ 60
Reflections collected	7172	11855	12119
Independent reflections	784 [ $R_{\text{int}} = 0.1277$ ]	2595 [ $R_{\text{int}} = 0.0563$ ]	1810 [ $R_{\text{int}} = 0.1261$ ]
Completeness to $\theta$	99%	99%	99%
Data / restraints / parameters	784 / 3 / 28	2595 / 9 / 82	1810 / 5 / 59
GOF	3.18	2.19	2.80
R indices [ $I > 2\sigma(I)$ ]	$R_{\text{obs}} = 0.0575$ $wR_{\text{obs}} = 0.1356$	$R_{\text{obs}} = 0.0555$ $wR_{\text{obs}} = 0.1099$	$R_{\text{obs}} = 0.0597$ $wR_{\text{obs}} = 0.1254$
R indices [all data]	$R_{\text{all}} = 0.0677$ $wR_{\text{all}} = 0.1361$	$R_{\text{all}} = 0.0898$ $wR_{\text{all}} = 0.1126$	$R_{\text{all}} = 0.0863$ $wR_{\text{all}} = 0.1270$
Largest diff. peak and hole (e <sup>-</sup> Å <sup>-3</sup> )	1.84 and -2.31	5.69 and -1.65	3.32 and -3.20

$$R = \sum ||F_o| - |F_c|| / \sum |F_o|, wR = \{ \sum [w(|F_o|^2 - |F_c|^2)^2] / \sum [w(|F_o|^4)] \}^{1/2} \text{ and } w = 1 / (\sigma^2(I) + 0.0004I^2)$$

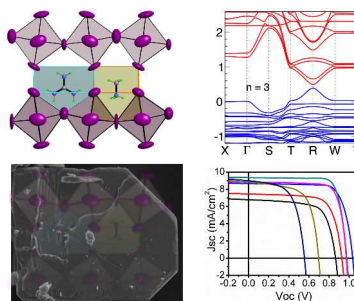
**Table 3.** Bond lengths [ $\text{\AA}$ ] and angles (degrees) for  $\text{GAMAPbI}_4$ ,  $\text{GAMA}_2\text{Pb}_2\text{I}_7$ , and  $\text{GAMA}_3\text{Pb}_3\text{I}_{10}$  at 293 K with estimated standard deviations in parentheses.

<b>GAMAPbI<sub>4</sub></b>			
Label	Distances	Label	Angles
Pb(1)-I(1)	3.181(2)	Pb(1)-I(2)-Pb(1)'	180.0(5)
Pb(1)-I(2)	3.2143(6)	Pb(1)-I(3)-Pb(1)'	159.04(13)
Pb(1)-I(3)	3.1673(8)		
<b>GAMA<sub>2</sub>Pb<sub>2</sub>I<sub>7</sub></b>			
Label	Distances	Label	Angles
Pb(1)-I(1)	3.168(3)	Pb(1)-I(1)-Pb(1)'	159.8(4)
Pb(1)-I(4)	3.271(9)	Pb(2)-I(2)-Pb(2)'	159.4(5)
Pb(1)-I(5)	3.121(7)	Pb(1)-I(4)-Pb(2)	166.13(14)
Pb(1)-I(6)	3.1910(6)	Pb(1)-I(6)-Pb(1)'	173.9(3)
Pb(1)-I(8)	3.181(3)	Pb(1)-I(8)-Pb(1)'	164.9(5)
Pb(2)-I(2)	3.205(4)	Pb(2)-I(9)-Pb(2)'	165.1(4)
Pb(2)-I(3)	3.097(7)		
Pb(2)-I(4)	3.206(9)		
Pb(2)-I(7)	3.1865(4)		
Pb(2)-I(9)	3.145(3)		
<b>GAMA<sub>3</sub>Pb<sub>3</sub>I<sub>10</sub></b>			
Label	Distances	Label	Angles
Pb(1)-I(5)	3.154(3)	Pb(2)-I(4)-Pb(2)'	162.70(14)
Pb(1)-I(6)	3.1760(7)	Pb(1)-I(5)-Pb(2)	167.66(11)
Pb(1)-I(7)	3.1280(7)	Pb(1)-I(6)-Pb(1)'	180.0(5)
Pb(2)-I(1)	3.092(2)	Pb(1)-I(7)-Pb(1)'	167.50(19)
Pb(2)-I(2)	3.1663(13)		
Pb(2)-I(3)	3.1779(7)		
Pb(2)-I(4)	3.1294(13)		
Pb(2)-I(5)	3.264(3)		

**Table 4.** Solar cell device parameters for  $\text{GAMA}_3\text{Pb}_3\text{I}_{10}$  as a function of the delay in the anti-solvent dripping. The average PCE is obtained from at least ten devices at each condition.

Delay time (s)	Jsc [ $\text{mA}/\text{cm}^2$ ]	Voc [V]	FF [%]	$\eta$ [%]
3 s	6.781	0.863	69.07	4.04 ( $3.90 \pm 0.18$ )
5 s	7.446	0.925	71.86	4.95 ( $4.33 \pm 0.40$ )
10 s	8.668	1.033	76.08	6.81 ( $6.14 \pm 0.36$ )
20 s	9.357	0.974	79.68	7.26 ( $6.69 \pm 0.47$ )
30 s	8.833	0.970	78.01	6.68 ( $6.30 \pm 0.59$ )
40 s	8.821	0.695	65.44	4.01 ( $3.84 \pm 0.19$ )
50 s	8.989	0.554	60.83	3.03 ( $2.72 \pm 0.28$ )

TOC Image



## Supporting Information

### **New Type of 2D Perovskites with Alternating Cations in the Interlayer Space, $(\text{C}(\text{NH}_2)_3)(\text{CH}_3\text{NH}_3)_n\text{Pb}_n\text{I}_{3n+1}$ : Structure, Properties and Photovoltaic Performance**

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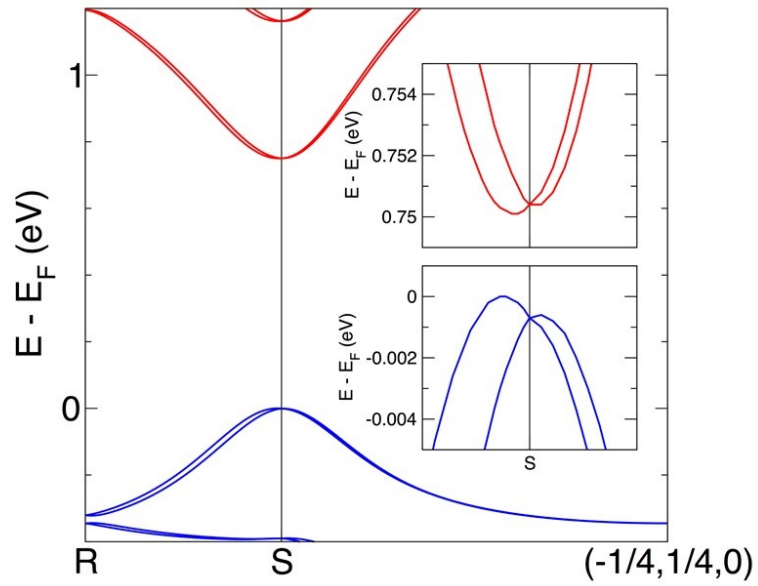
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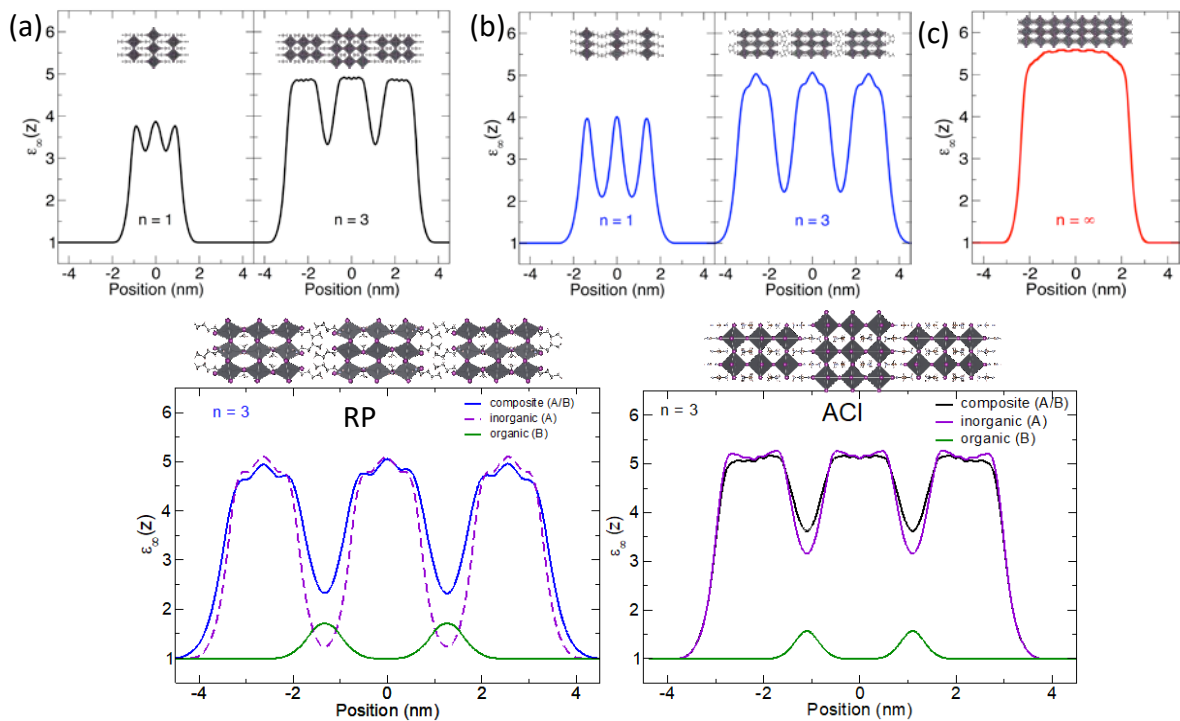
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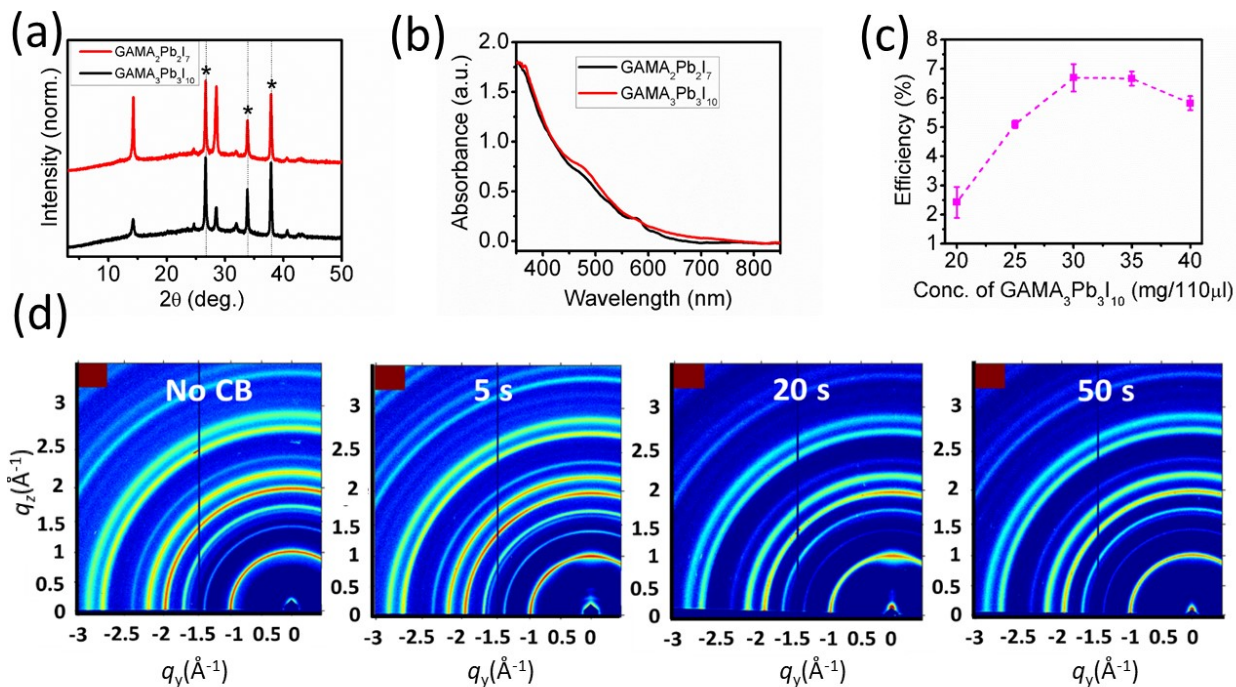


**Figure S1.** Closeup view of the electronic band structure of the  $n = 2$  member of the  $(\text{GA})(\text{MA})_n\text{Pb}_n\text{I}_{3n+1}$  ACI perovskites, highlighting the Rashba splitting of the valence and conduction band extrema around the S point of the Brillouin zone.

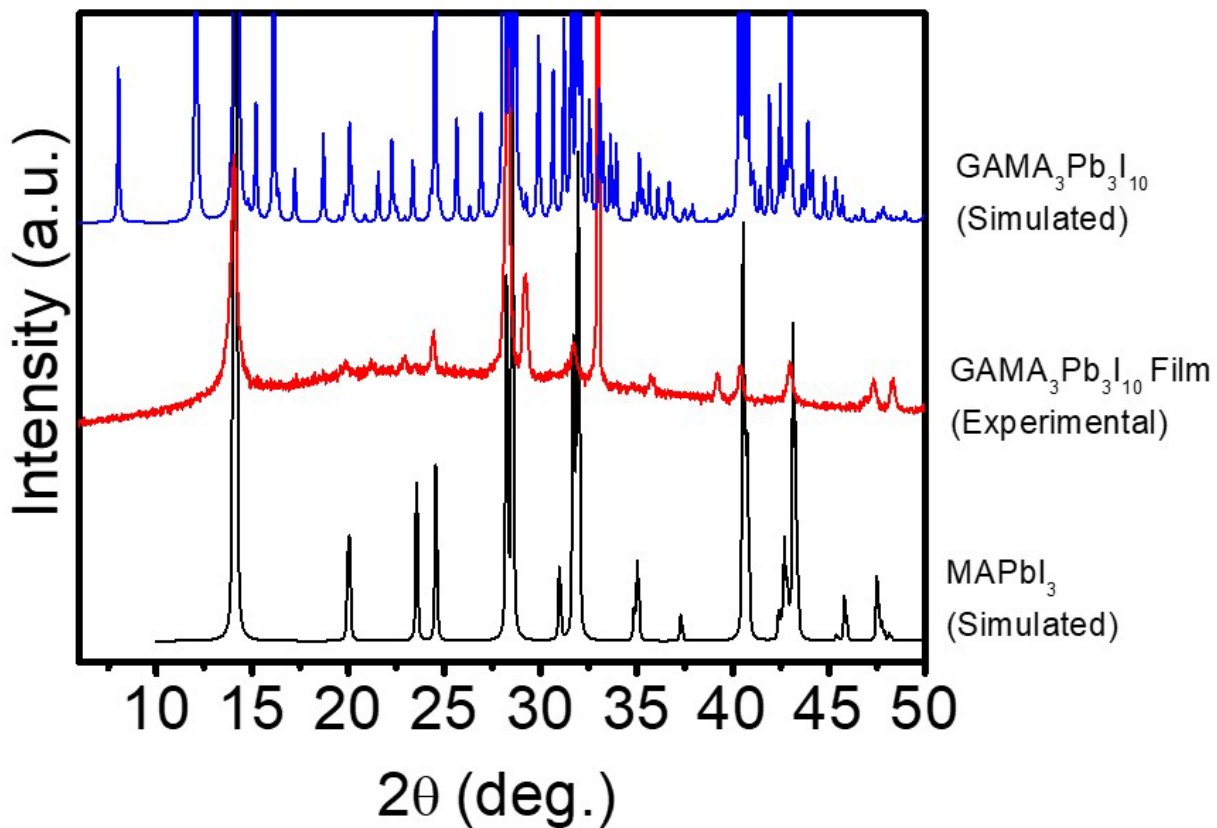




**Figure S2.** Dielectric profiles for (a)  $(GA)(MA)_nPb_nI_{3n+1}$ , (b)  $(BA)_2(MA)_{n-1}Pb_nI_{3n+1}$  for  $n = 1$  and  $n = 3$ . (c) Dielectric profile for bulk 3D  $MAPbI_3$ . (d) Comparison between the dielectric profiles of RP and ACI layered perovskites with the same  $n$ -member, illustrating the net contribution of the spacer cations to the dielectric profile (green trace).



**Figure S3.** (a) PXR D patterns of thin films of  $(GA)(MA)_2Pb_2I_7$  and  $(GA)(MA)_3Pb_3I_{10}$  obtained from the chlorobenzene (CB) anti-solvent method. (b) Optical absorption spectra of thin films of  $(GA)(MA)_2Pb_2I_7$  and  $(GA)(MA)_3Pb_3I_{10}$  obtained from the anti-solvent method. (c) Efficiency vs. precursor solution concentration for devices made of  $(GA)(MA)_3Pb_3I_{10}$  using the anti-solvent method. (d) GIWAXS patterns of thin films of  $(GA)(MA)_3Pb_3I_{10}$  as a function of the delay in dripping time of the anti-solvent.



**Figure S4.** Close up view of the PXRD pattern of a thin film of  $(\text{GA})(\text{MA})_3\text{Pb}_3\text{I}_{10}$  obtained from the anti-solvent method, referenced against the calculated patterns of  $(\text{GA})(\text{MA})_3\text{Pb}_3\text{I}_{10}$  and  $\text{MAPbI}_3$ , highlighting the formation of the 2D ACI perovskite on the substrate.

**Table S1.** Atomic coordinates ( $\times 10^4$ ) and equivalent isotropic displacement parameters ( $\text{\AA}^2 \times 10^3$ ) for GAMAPbI<sub>4</sub> at 293 K with estimated standard deviations in parentheses.

Label	x	y	z	Occupancy	$U_{\text{eq}}^*$
Pb(1)	0	0	0	1	32(1)
I(1)	0	418(2)	1667(2)	1	66(1)
I(2)	5000	0	0	1	69(2)
I(3)	0	7500	306(2)	1	78(2)
N(1)	5000	2500	1110(50)	1	220(30)
N(2)	0	7500	2231(15)	1	54(5)
N(3)	0	8461(14)	3279(13)	1	54(5)
C(1)	5000	2500	1910(50)	1	220(30)
C(2)	0	7500	2948(15)	1	54(5)
H(1n3)	0	8490.85	3740.93	1	64.8
H(2n3)	0	9050.08	3031.18	1	64.8
H(1n2)	0	6895.2	1999.53	1	64.8
H(2n2)	0	8104.8	1999.53	1	64.8
H(1n1)	5930.53	2950.49	956.76	0.25	265.7
H(2n1)	5290.76	1858.9	956.76	0.25	265.7
H(3n1)	3778.71	2690.61	956.76	0.25	265.7
H(1c1)	6221.29	2309.39	2061.62	0.25	265.7
H(2c1)	4709.24	3141.1	2061.62	0.25	265.7
H(3c1)	4069.47	2049.51	2061.62	0.25	265.7

\* $U_{\text{eq}}$  is defined as one third of the trace of the orthogonalized  $U_{ij}$  tensor.

**Table S2.** Atomic coordinates ( $\times 10^4$ ) and equivalent isotropic displacement parameters ( $\text{\AA}^2 \times 10^3$ ) for  $\text{GAMA}_2\text{Pb}_2\text{I}_7$  at 293 K with estimated standard deviations in parentheses.

Label	x	y	z	Occupancy	$U_{\text{eq}}^*$
Pb(1)	5000	2486(2)	3875(1)	1	32(2)
Pb(2)	5000	2486(2)	1826(1)	1	33(2)
I(1)	5000	0	4052(3)	1	83(5)
I(2)	5000	5000	2009(4)	1	82(4)
I(3)	5000	2889(7)	852(2)	1	69(3)
I(4)	5000	2175(3)	2840(3)	1	84(2)
I(5)	5000	2900(6)	4856(2)	1	67(3)
I(6)	0	2516(10)	3822(3)	1	72(3)
I(7)	0	2473(10)	1825(3)	1	75(3)
I(8)	5000	5000	3742(4)	1	119(7)
I(9)	5000	0	1696(3)	1	109(7)
N(1)	0	0	2786(17)	1	103(19)
N(2)	0	5000	2587(1)	1	500(100)
N(3)	0	5000	1276(13)	1	65(14)
N(4)	5000	5000	-260(30)	1	190(40)
N(5)	5000	932(1)	-180(20)	1	140(30)
N(6)	5000	0	460(20)	1	140(30)
N(7)	5000	986(12)	5810(11)	1	33(7)
N(8)	5000	0	5208(10)	1	33(7)
C(1)	0	0	3264(17)	1	103(19)
C(2)	0	5000	3065(1)	1	500(100)
C(3)	0	5000	798(13)	1	65(14)
C(4)	5000	5000	220(30)	1	190(40)
C(5)	5000	0	30(20)	1	140(30)
C(6)	5000	0	5638(10)	1	33(7)
H(1n1)	873.54	480.25	2693.79	0.25	123.3
H(2n1)	381.84	-624.48	2693.79	0.25	123.3
H(3n1)	-1255.38	144.23	2693.79	0.25	123.3
H(1n2)	1277.74	4921.35	2494.7	0.25	596.4
H(2n2)	-772.93	4477.13	2494.7	0.25	596.4
H(3n2)	-504.8	5601.52	2494.7	0.25	596.4
H(1n3)	-1011.97	4595.94	1368.49	0.25	78.5
H(2n3)	1194.73	4756.77	1368.49	0.25	78.5

H(3n3)	-182.76	5647.29	1368.49	0.25	78.5
H(1n4)	3758.24	4828	-351.94	0.25	229.2
H(2n4)	5327.7	5632.37	-351.94	0.25	229.2
H(3n4)	5914.06	4539.63	-351.94	0.25	229.2
H(1n5)	5000	932.01	-461.06	1	167.6
H(2n5)	5000	1532.67	-45.14	1	167.6
H(1n6)	5000	-600.66	600.24	0.5	167.6
H(2n6)	5000	600.66	600.24	0.5	167.6
H(1n7)	5000	1064.18	6085.52	1	39.8
H(2n7)	5000	1544.4	5645.3	1	39.8
H(1n8)	5000	-600.66	5069.11	0.5	39.8
H(2n8)	5000	600.66	5069.11	0.5	39.8
H(1c1)	966.4	-528.76	3366.27	0.25	123.3
H(2c1)	418.1	689.59	3366.27	0.25	123.3
H(3c1)	-1384.5	-160.83	3366.27	0.25	123.3
H(1c2)	1416.32	4946.5	3167.17	0.25	596.4
H(2c2)	-616.97	5649.92	3167.17	0.25	596.4
H(3c2)	-799.35	4403.58	3167.17	0.25	596.4
H(1c3)	846.04	5579.56	696.02	0.25	78.5
H(2c3)	564.88	4337.96	696.02	0.25	78.5
H(3c3)	-1410.92	5082.47	696.02	0.25	78.5
H(1c4)	4707.54	4293.9	320.55	0.25	229.2
H(2c4)	6349.82	5224.37	320.55	0.25	229.2
H(3c4)	3942.64	5481.73	320.55	0.25	229.2

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\* $U_{eq}$  is defined as one third of the trace of the orthogonalized  $U_{ij}$  tensor.

**Table S3.** Atomic coordinates ( $\times 10^4$ ) and equivalent isotropic displacement parameters ( $\text{\AA}^2 \times 10^3$ ) for  $\text{GAMA}_3\text{Pb}_3\text{I}_{10}$  at 293 K with estimated standard deviations in parentheses.

Label	x	y	z	Occupancy	$U_{\text{eq}}^*$
Pb(1)	0	0	0	1	35(1)
Pb(2)	0	12(1)	1451(1)	1	33(1)
I(1)	0	5406(2)	2144(1)	1	74(1)
I(2)	0	7500	1335(1)	1	84(2)
I(3)	5000	0(3)	1427(1)	1	80(1)
I(4)	0	2500	1558(1)	1	88(2)
I(5)	0	283(2)	713(1)	1	91(2)
I(6)	5000	0	0	1	128(2)
I(7)	0	7500	77(2)	1	151(3)
N(1)	5000	7500	953(1)	1	530(90)
N(2)	-5000	2500	839(18)	1	230(30)
N(3)	0	7500	3166(19)	1	190(20)
N(4)	5000	2500	2614(7)	1	60(5)
N(5)	5000	1541(14)	2163(6)	1	60(5)
C(1)	5000	7500	612(1)	1	530(90)
C(2)	-5000	2500	498(18)	1	230(30)
C(3)	0	7500	2825(19)	1	190(20)
C(4)	5000	2500	2306(7)	1	60(5)
H(1n1)	6282.98	7574.81	1019.02	0.25	633.3
H(2n1)	4231.65	8030.03	1019.02	0.25	633.3
H(3n1)	4485.37	6895.16	1019.02	0.25	633.3
H(1n2)	-6285.59	2437.95	905.09	0.25	273.8
H(2n2)	-4251.98	1962.44	905.09	0.25	273.8
H(3n2)	-4462.43	3099.62	905.09	0.25	273.8
H(1n3)	-1285.48	7562.63	3232	0.25	222.8
H(2n3)	536.54	6900.14	3232	0.25	222.8
H(3n3)	748.94	8037.23	3232	0.25	222.8
H(1n4)	5000	3105.77	2712.43	0.5	72.3
H(2n4)	5000	1894.23	2712.43	0.5	72.3
H(1n5)	5000	1514.89	1965.17	1	72.3
H(2n5)	5000	948.27	2268.09	1	72.3
H(1c1)	3886.23	7953.88	539.15	0.25	633.3
H(2c1)	4787.21	6780.46	539.15	0.25	633.3

H(3c1)	6326.56	7765.66	539.15	0.25	633.3
H(1c2)	-6200.48	2107.99	425.22	0.25	273.8
H(2c2)	-3735.01	2165.06	425.22	0.25	273.8
H(3c2)	-5064.51	3226.95	425.22	0.25	273.8
H(1c3)	98.44	6774.04	2752.13	0.25	222.8
H(2c3)	1181.83	7906.52	2752.13	0.25	222.8
H(3c3)	-1280.27	7819.44	2752.13	0.25	222.8

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\* $U_{eq}$  is defined as one third of the trace of the orthogonalized  $U_{ij}$  tensor.



**Table S4.** Anisotropic displacement parameters ( $\text{\AA}^2 \times 10^3$ ) for GAMAPbI<sub>4</sub> at 293 K with estimated standard deviations in parentheses.

Label	U <sub>11</sub>	U <sub>22</sub>	U <sub>33</sub>	U <sub>12</sub>	U <sub>13</sub>	U <sub>23</sub>
Pb(1)	25(1)	28(1)	42(1)	0	0	3(1)
I(1)	90(2)	63(2)	44(2)	0	0	-2(2)
I(2)	21(2)	111(3)	74(2)	0	0	21(2)
I(3)	155(4)	22(2)	57(2)	0	0	0

The anisotropic displacement factor exponent takes the form:  $-2\pi^2[h^2a^{*2}U_{11} + \dots + 2hka^*b^*U_{12}]$ .

**Table S5.** Anisotropic displacement parameters ( $\text{\AA}^2 \times 10^3$ ) for GAMA<sub>2</sub>Pb<sub>2</sub>I<sub>7</sub> at 293 K with estimated standard deviations in parentheses.

Label	U <sub>11</sub>	U <sub>22</sub>	U <sub>33</sub>	U <sub>12</sub>	U <sub>13</sub>	U <sub>23</sub>
Pb(1)	24(2)	26(3)	47(2)	0	0	1(2)
Pb(2)	37(2)	28(3)	34(2)	0	0	0(2)
I(1)	139(12)	35(5)	74(6)	0	0	0
I(2)	102(9)	40(6)	103(7)	0	0	0
I(3)	97(7)	75(5)	36(3)	0	0	34(2)
I(4)	107(3)	119(3)	26(2)	0	0	-20(4)
I(5)	91(7)	67(4)	43(3)	0	0	20(2)
I(6)	18(3)	128(8)	72(4)	0	0	12(4)
I(7)	26(3)	125(8)	72(3)	0	0	-25(4)
I(8)	233(17)	6(4)	119(8)	0	0	0
I(9)	248(19)	13(5)	65(5)	0	0	0

The anisotropic displacement factor exponent takes the form:  $-2\pi^2[h^2a^{*2}U_{11} + \dots + 2hka^*b^*U_{12}]$ .

**Table S6.** Anisotropic displacement parameters ( $\text{\AA}^2 \times 10^3$ ) for GAMA<sub>3</sub>Pb<sub>3</sub>I<sub>10</sub> at 293 K with estimated standard deviations in parentheses.

Label	U <sub>11</sub>	U <sub>22</sub>	U <sub>33</sub>	U <sub>12</sub>	U <sub>13</sub>	U <sub>23</sub>
Pb(1)	37(1)	34(1)	35(1)	0	0	2(1)
Pb(2)	31(1)	29(1)	38(1)	0	0	0(1)
I(1)	116(2)	72(2)	35(2)	0	0	-10(1)
I(2)	130(4)	25(2)	99(3)	0	0	0
I(3)	26(1)	123(2)	90(2)	0	0	-15(2)
I(4)	172(4)	25(2)	68(3)	0	0	0
I(5)	120(2)	128(2)	26(2)	0	0	-2(2)
I(6)	25(2)	250(5)	108(4)	0	0	-1(5)
I(7)	304(8)	21(2)	128(5)	0	0	0

The anisotropic displacement factor exponent takes the form:  $-2\pi^2[h^2a^{*2}U_{11} + \dots + 2hka^*b^*U_{12}]$ .

**Table S7.** Calculated band dispersion (meV) along the perovskite layer stacking direction in reciprocal space for ACI (GA)(MA)<sub>n</sub>Pb<sub>n</sub>I<sub>3n+1</sub> perovskites with n = 1-3.

<i>n</i> -member	<b>1</b>	<b>2</b>	<b>3</b>
<i>k</i> -direction	W-T	Γ-Y	W-T
VBM (meV)	48	63	< 1
CBM (meV)	11	26	4